ADS54J54 四通道 14 位 500MSPS ADC

1 特性

- 4 通道、14 位 500MSPS 模数转换器 (ADC)
- 模拟输入缓冲器，具有高阻抗输入
- 灵活的输入时钟缓冲器，支持 1 分频、2 分频和 4 分频
- 1.25V_{PP} 差分满量程输入
- JESD204B 串行接口
  - 符合子类 1，速率高达 5Gbps
  - 每个 ADC 一条通道，速率高达 250Msps
  - 每个 ADC 两条通道，速率高达 500Msps
- 64 引脚四方扁平无引线 (QFN) 封装 (9mm x 9mm)
- 主要规格：
  - 功率耗散：875mW/ch
  - 输入带宽 (3dB)：900MHz
  - 孔径抖动：98fs rms
  - 通道隔离：85dB
  - f_{in} = 170MHz、1.25 V_{PP}、单通道、2x 抽取滤波器、–1dBFS 条件下的性能
    - 信噪比 (SNR)：67.2dBFS
    - 无杂散动态范围 (SFDR)：85dBc（HD2，HD3）；95dBFS（非 HD2，HD3）
  - f_{in} = 370MHz、1.25 V_{PP}、双通道、无抽取滤波器、–1dBFS 条件下的性能
    - SNR：64.7dBFS
    - SFDR：75dBc（HD2，HD3）；83dBFS（非 HD2，HD3）

2 应用

- 多载波、多模式、多频带蜂窝接收器
  - TDD-LTE、FDD-LTE、CDMA、WCMDA、CMDA2k 和 GSM
- 微波回程连线
- 无线中继器
- 分布式天线系统 (DAS)
- 无线宽带
- 超宽带软件定义无线电
- 数据采集
- 测试和测量仪表
- 信号智能和干扰
- 雷达和卫星系统
- 电缆基础设施

3 说明

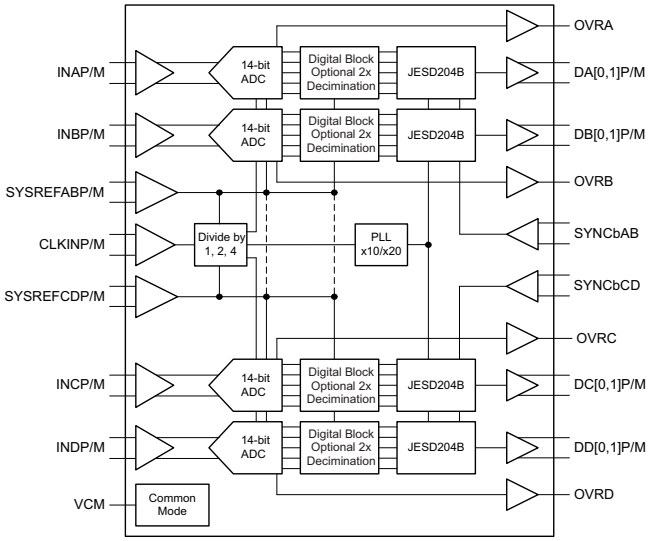
ADS54J54 是一款低功耗、高带宽 14 位、500MSPS 四通道模数转换器 (ADC)。该器件支持 JESD204B 串行接口，数据传输速率高达 5Gbps，每个 ADC 可支持 1 或 2 条通道。已缓冲模拟输入在大大减少采样保持毛刺脉冲能量的同时，在宽频率范围内提供统一的输入阻抗。采样时钟分频器可实现更灵活的系统时钟架构设计。ADS54J54 以超低功耗在宽输入频率范围内提供出色的无杂散动态范围 (SFDR)。该器件具有可选 2x 抽取滤波器，可提供高通或低通滤波器两种模式。

器件信息(1)

器件型号	封装	封装尺寸（标称值）
ADS54J54	VQFN (64)	9.00mm x 9.00mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。

简化原理图



本文档旨在为方便起见，提供有关 TI 产品中文版本的信息，以确认产品的概要。 有关适用的官方英文版本的最新信息，请访问 www.ti.com，其内容始终优先。 TI 不保证翻译的准确性和有效性。 在实际设计之前，请务必参考最新版本的英文版本。

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4 修订历史记录

Changes from Original (January 2015) to Revision A **Page**

- Added list item in *Device and Register Initialization*: "Write the data in 表 5 to.." ... 33
- Added 表 5 ... 33

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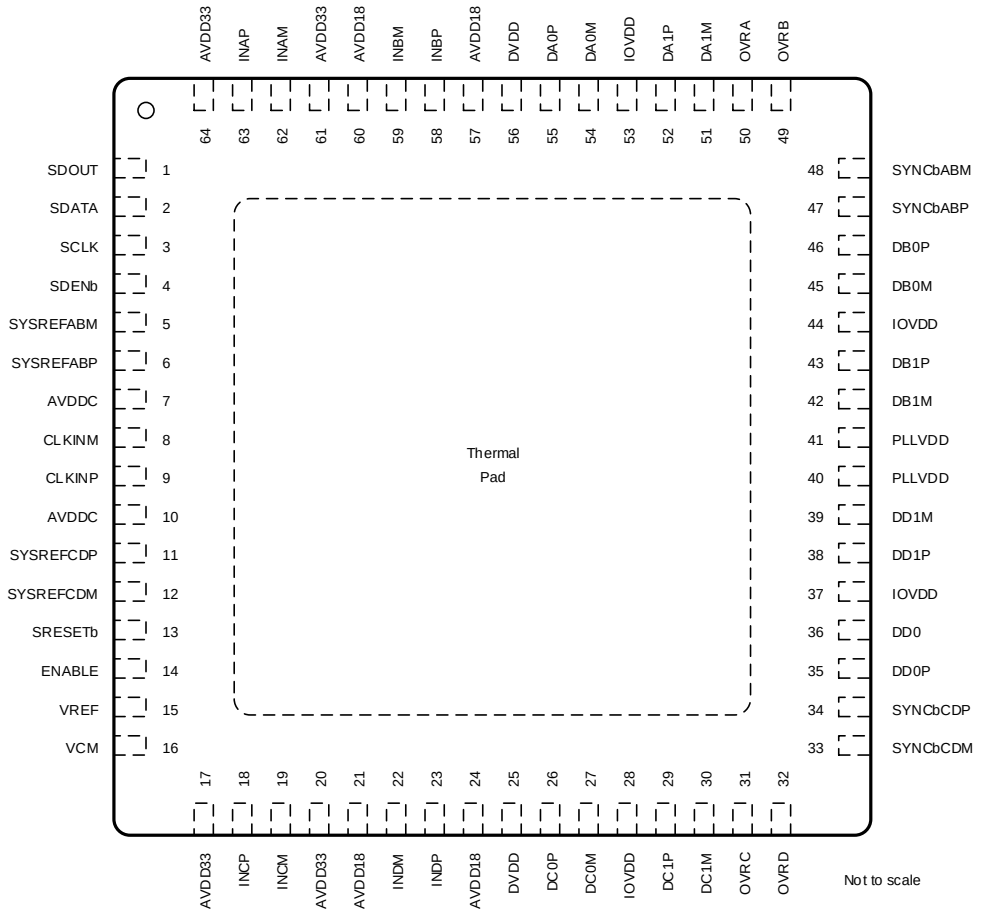
5 Pin Configuration and Functions

ADS54J54
RGC 64 Pin Package
Top View



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
INPUT OR REFERENCE			
INAP, INAM	63, 62	I	Differential analog input for channel A
INBP, INBM	58, 59	I	Differential analog input for channel B
INCP, INCM	18, 19	I	Differential analog input for channel C
INDP, INDM	23, 22	I	Differential analog input for channel D
VCM	16	O	Common mode output voltage to bias analog inputs, Vcm = 2.0 V
VREF	15	O	Voltage reference output. A 0.1-µF bypass capacitor to ground close to the pin is recommended
CLOCK/SYNC			
CLKINP, CLKINM	9, 8	I	Differential clock input for channel
SYSREFABP, SYSREFABM	6, 5	I	LVDS input with internal 100-Ω termination. External SYSREF input for channels A, B, C, and D
SYSREFCDP, SYSREFCDM	11, 12	I	LVDS input with internal 100-Ω termination. External SYSREF input for channels C and D if output rate of channel A/B is different from channel C/D.

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Pin Functions (continued)

PIN		I/O	DESCRIPTION
NAME	NO.		
CONTROL OR SERIAL			
ENABLE	14	I	Chip enable. Active high. Power down functionality can be configured through SPI register setting and exercised using the ENABLE pin. Internal 51-kΩ pulldown resistor.
SCLK	3	I	Serial interface clock input
SDATA	2	I/O	Bidirectional serial data in 3-pin mode. In 4-pin interface, the SDATA pin is an input only.
SDENb	4	I	Serial interface enable
SDOUT	1	O	Serial interface data output
SRESETb	13	I	Hardware reset. Active low. Initializes internal registers during high to low transition. This pin has an internal 51-kΩ pullup resistor.
DATA OUTPUT INTERFACE			
DA[0,1]P, DA[0,1]M	55, 54, 52, 51	O	JESD204B output interface for channel A
DB[0,1]P, DB[0,1]M	46, 45, 43, 42	O	JESD204B output interface for channel B
DC[0,1]P, DC[0,1]M	26, 27, 29, 30	O	JESD204B output interface for channel C
DD[0,1]P, DD[0,1]M	35, 36, 38, 39	O	JESD204B output interface for channel D
OVRA	50	I/O	Fast over-range indicator channel A.
OVRB	49	O	Fast over-range indicator channel B.
OVRC	31	I/O	Fast over-range indicator channel C.
OVRD	32	O	Fast over-range indicator channel D.
SYNCbABP, SYNCbABM	47, 48	I	SYNCb input for JESD204B interface for channel A/B, internal 100-Ω termination
SYNCbCDP, SYNCbCDM	34, 33	I	SYNCb input for JESD204B interface for channel C/D, internal 100-Ω termination
POWER SUPPLY			
AVDDC	7, 10	I	Clock 1.8-V power supply
AVDD18	21, 24, 57, 60	I	Analog 1.9-V power supply
AVDD33	17, 20, 61, 64	I	Analog 3.3-V power supply
DVDD	25, 56	I	Digital 1.8-V power supply
GND	PowerPAD™	I	Ground
IOVDD	28, 37, 44, 53	I	JESD204B output interface 1.8-V power supply
PLLVDD	40, 41	I	PLL 1.8-V power supply

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage	AVDD33	–0.3	3.6	V
	AVDD18	–0.3	2.1	
	AVDDC	–0.3	2.1	
	DVDD	–0.3	2.1	
	IOVDD	–0.3	2.1	
	PLLVDD	–0.3	2.1	
Voltage between AGND and DGND		–0.3	0.3	V
Voltage applied to input pins	INAP, INBP, INCP, INDP, INAM, INBM, INCM, INDM	–0.3	3	V
	CLKINP, CLKINM	–0.3	AVDD18 + 0.3 V	
	SYNCbABP, SYNCbABM, SYNCbCDP, SYNCbCDM	–0.3	AVDD18 + 0.3 V	
	SYSREFABP, SYSREFABM, SYSREFCDP, SYSREFCDM	–0.3	AVDD18 + 0.3 V	
	SCLK, SDENb, SDATA, SRESETb, ENABLE	–0.3	DVDD + 0.5 V	
Operating free-air temperature, T_A		–40	85	ºC
Operating junction temperature, T_J (2)			125	ºC
Storage temperature, T_{stg}		–65	150	°C

(1) Stresses beyond those listed as *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated as *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Prolonged use at this junction temperature may increase the device failure-in-time (FIT) rate.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±1000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
	ADC clock frequency	250		500	MSPS
	Resolution	14		14	bits
Supply	AVDD33	3.15	3.3	3.45	V
	AVDD18	1.8	1.9	2	
	AVDDC	1.7	1.8	1.9	
	DVDD	1.7	1.8	1.9	
	IOVDD	1.7	1.8	1.9	
	PLLVDD	1.7	1.8	1.9	
T_A	Operating free-air temperature	–40		85	°C
T_J	Operating junction temperature			125	°C

6.4 Thermal Information

Thermal Metric(1)		RGC (64 PINS)	UNIT
$R_{\Theta JA}$	Junction-to-ambient thermal resistance	23.5	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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Thermal Information (continued)

Thermal Metric[1]		RGC (64 PINS)	UNIT
$R_{\Theta JC(top)}$	Junction-to-case, top	7.0	°C/W
$R_{\Theta JB}$	Junction-to-board thermal resistance	2.6	°C/W
φ_{JT}	Junction-to-top of package	0.1	°C/W
φ_{JB}	Junction-to-board characterization parameter	2.6	°C/W
$R_{\Theta JC(bot)}$	Junction-to-case, bottom	0.3	°C/W

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6.5 Electrical Characteristics

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, ADC sampling rate = 500 MSPS, 50% clock duty cycle, AVDD33 = 3.3 V; AVDD18 = 1.9 V; AVDDC, DVDD, IOVDD, PLLVDD = 1.8 V, –1-dBFS differential input, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
POWER SUPPLY							
I_{AVDD33}	3.3-V analog supply current				500		mA
I_{AVDD18}	1.9-V analog supply current				320		mA
I_{AVDDC}	1.8-V clock supply current				18		mA
I_{DVDD}	1.8-V digital supply current	4-channel decimation filter			323		mA
		4-channel bypass digital mode			324		
		2-channel decimation filter, 2-channel bypass digital mode			324		
I_{IOVDD}	I/O voltage supply current	2 lanes per ADC			373		mA
		1 lane per ADC			185		
I_{PLLVDD}	PLL voltage supply current				42		mA
Pdis	Total power dissipation	4-channel bypass digital mode			3.46	3.7	W
		4-channel decimation filter			3.34		
		4-channel decimation filter, 1 lane per ADC			3.27		
		2-channel decimation filter, 2-channel bypass digital mode			3.51		
Deep sleep mode power					791		mW
Wake-up time from deep sleep mode		SNR > 60 dB			1.4		ms
Light sleep mode power					1.68		W
Wake-up time from light sleep mode		SNR > 60 dB			8		µs
ANALOG INPUTS							
Differential input full-scale				1	1.25	1.5	Vpp
Input common mode voltage					V_{CM} ± 50 mV		V
Input resistance	Differential at DC				1		kΩ
Input capacitance	Each input to GND				2.75		pF
VCM	Common mode voltage output				2.18		V
Analog input bandwidth (–3 dB)					900		MHz
INL		Integral nonlinearity			±3		LSB
DNL		Dynamic nonlinearity		–1	±0.9		LSB
Gain error					±2.24%		
Offset error					±1.91		mV
CHANNEL-TO-CHANNEL ISOLATION							
Crosstalk (1)		Near channel	f_{IN} = 170 MHz		85		dB
		Far channel	f_{IN} = 170 MHz		95		
CLOCK INPUT							
Input clock frequency				250		2000 (2)	MHz
Input clock amplitude				0.4	1.5		Vpp
Input clock duty cycle				45%	50%	55%	
Internal clock biasing					0.9		V

(1) Crosstalk is measured with a –1-dBFS input signal on aggressor channel and no input on victim channel.
(2) CLK / 4 mode

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6.6 Electrical Characteristics: 250 MSPS Output, 2x Decimation Filter

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, ADC sampling rate = 500 MSPS, 50% clock duty cycle, AVDD33 = 3.3 V; AVDD18 = 1.9 V; AVDDC, DVDD, IOVDD, PLLVDD = 1.8 V, –1-dBFS differential input, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SNR	Signal-to-noise ratio	f_{IN} = 10 MHz		68.3		dBFS
		f_{IN} = 100 MHz		68.2		
		f_{IN} = 170 MHz		67.2		
		f_{IN} = 310 MHz		67.6		
		f_{IN} = 450 MHz		66.8		
HD2	Second harmonic distortion	f_{IN} = 10 MHz		85		dBc
		f_{IN} = 100 MHz		85		
		f_{IN} = 170 MHz		85		
		f_{IN} = 310 MHz		85		
		f_{IN} = 450 MHz		75		
HD3	Third harmonic distortion	f_{IN} = 10 MHz		85		dBc
		f_{IN} = 100 MHz		85		
		f_{IN} = 170 MHz		85		
		f_{IN} = 310 MHz		85		
		f_{IN} = 450 MHz		85		
SFDR (Non-HD2, Non-HD3)	Spur free dynamic range (excluding HD2 and HD3)	f_{IN} = 10 MHz		95		dBc
		f_{IN} = 100 MHz		95		
		f_{IN} = 170 MHz		95		
		f_{IN} = 310 MHz		90		
		f_{IN} = 450 MHz		85		
IMD3	2F1-F2, 2F2-F1, Ain = –7 dBFS	F_{IN} = 169 and 171 MHz		93		dBFS

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6.7 Electrical Characteristics: 500 MSPS Output

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, ADC sampling rate = 500 MSPS, 50% clock duty cycle, AVDD33 = 3.3 V; AVDD18 = 1.9 V; AVDDC, DVDD, IOVDD, PLLVDD = 1.8 V, –1-dBFS differential input, unless otherwise noted.

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
SNR	Signal-to-Noise Ratio	Bypass Digital Mode (14 bit)	f_{IN} = 10 MHz		65.3		dBFS
			f_{IN} = 100 MHz		65.2		
			f_{IN} = 170 MHz	61	64.9		
			f_{IN} = 370 MHz		64.7		
			f_{IN} = 450 MHz		64.6		
HD2	Second Harmonic Distortion		f_{IN} = 10 MHz		85		dBc
			f_{IN} = 100 MHz		85		
			f_{IN} = 170 MHz	70	85		
			f_{IN} = 370 MHz		75		
			f_{IN} = 450 MHz		75		
HD3	Third Harmonic Distortion		f_{IN} = 10 MHz		85		dBc
			f_{IN} = 100 MHz		85		
			f_{IN} = 170 MHz	70	85		
			f_{IN} = 370 MHz		85		
			f_{IN} = 450 MHz		85		
SFDR (Non-HD2, Non-HD3)	Spur Free Dynamic Range (excluding HD2 and HD3)		f_{IN} = 10 MHz		85		dBFS
			f_{IN} = 100 MHz		85		
			f_{IN} = 170 MHz	70	85		
			f_{IN} = 370 MHz		83		
			f_{IN} = 450 MHz		83		
IMD3	2F1-F2, 2F2-F1, Ain = –7 dBFS		f_{IN} = 169 and 171 MHz		87		dBFS

6.8 Electrical Characteristics: Sample Clock Timing Characteristics

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, ADC sampling rate = 500 MSPS, 50% clock duty cycle, AVDD33 = 3.3 V; AVDD18 = 1.9 V; AVDDC, DVDD, IOVDD, PLLVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted.

PARAMETER		MIN	TYP	MAX	UNIT
	Aperture jitter, RMS		98		fs rms
	Data latency		38		Sample clock cycles
	Fast over-range (OVR) latency		6		
t_{PDI}	Clock aperture delay		1.1		ns

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6.9 Electrical Characteristics: Digital Outputs

The DC specifications refer to the condition where the digital outputs are not switching, but are permanently at a valid logic level 0 or 1. AVDD33 = 3.3 V; AVDD18 = 1.9 V; AVDDC, DVDD, IOVDD, PLLVDD = 1.8 V.

PARAMETER		MIN	TYP	MAX	UNIT
DIGITAL OUTPUTS: JESD204B INTERFACE (DA[0,1], DB[0,1], DC[0,1], DD[0,1])					
Output differential voltage, |VOD|		450	577	750	mV
Transmitter short circuit current	Transmitter terminals shorted to any voltage between –0.25 and 1.45 V		45		mA
Single ended output impedance			50		Ω
Output capacitance	Output capacitance inside the device, from either output to ground		2		pF
Unit interval, UI	5.0 Gbps		200		ps
Rise and fall times			110		ps
Output jitter			57		ps
Serial output data rate			5.0		Gbps

6.10 Timing Requirements

		MIN	TYP	MAX	UNIT
DIGITAL INPUTS: SRESETb, SCLK, SDENb, SDATA, ENABLE, OVRA, OVRC, SYSREFCDP, SYSREFCDM					
High-level input voltage	All digital inputs support 1.8-V and 3.3-V logic levels	1.2			V
Low-level input voltage				0.4	V
High-level input current			50		µA
Low-level input current			–50		µA
Input capacitance			4		pF
DIGITAL OUTPUTS: SDOUT, OVRA, OVRB, OVRC, OVRD					
High-level output voltage	I_{Load} = –100 µA	DVDD – 0.2	DVDD		V
Low-level output voltage				0.2	V
DIGITAL INPUTS: SYNCbABP/M, SYNCbCDP/M, SYSREFABP/M, SYSREFCDP/M					
Input voltage VID		250	350	450	mV
Input common mode voltage VCM		0.4	0.9	1.4	V
$t_{S_SYSREFxx}$	Referenced to rising edge of input clock		100		ps
$t_{H_SYSREFxx}$	Referenced to rising edge of input clock		100		ps

6.11 Reset Timing

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_1	Power-on delay	Delay from power up to active-low RESET pulse	3			ms
t_2	Reset pulse duration	Active-low RESET pulse duration	20			ns
t_3	Register write delay	Delay from RESET disable to SDENb active	100			ns

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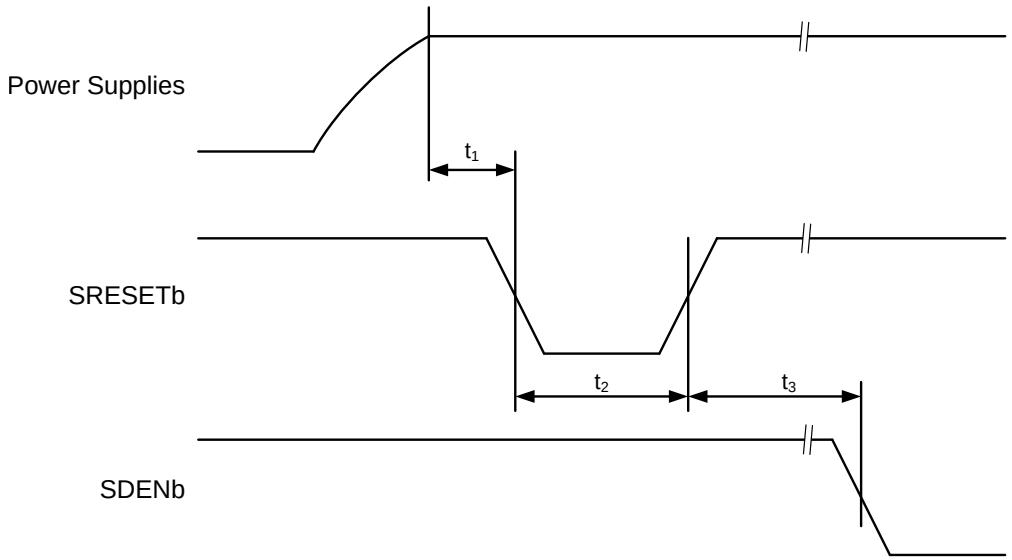
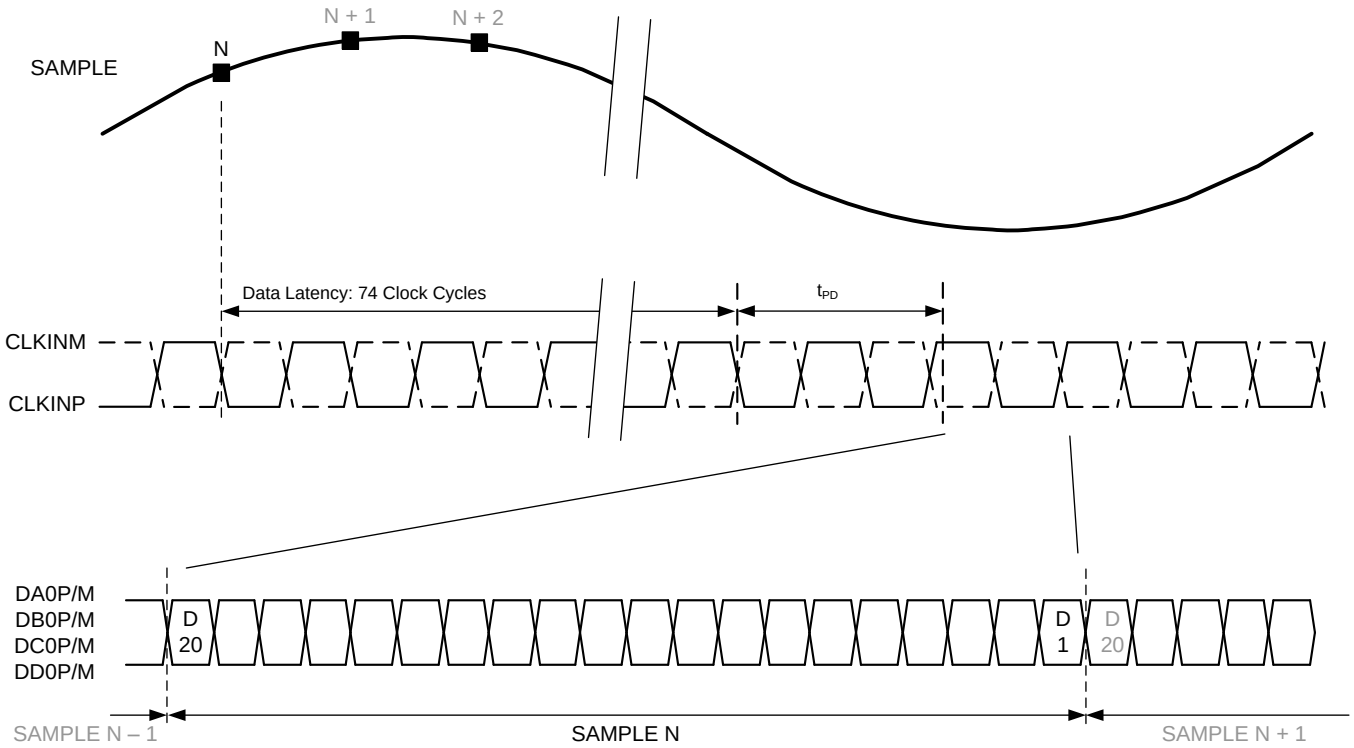
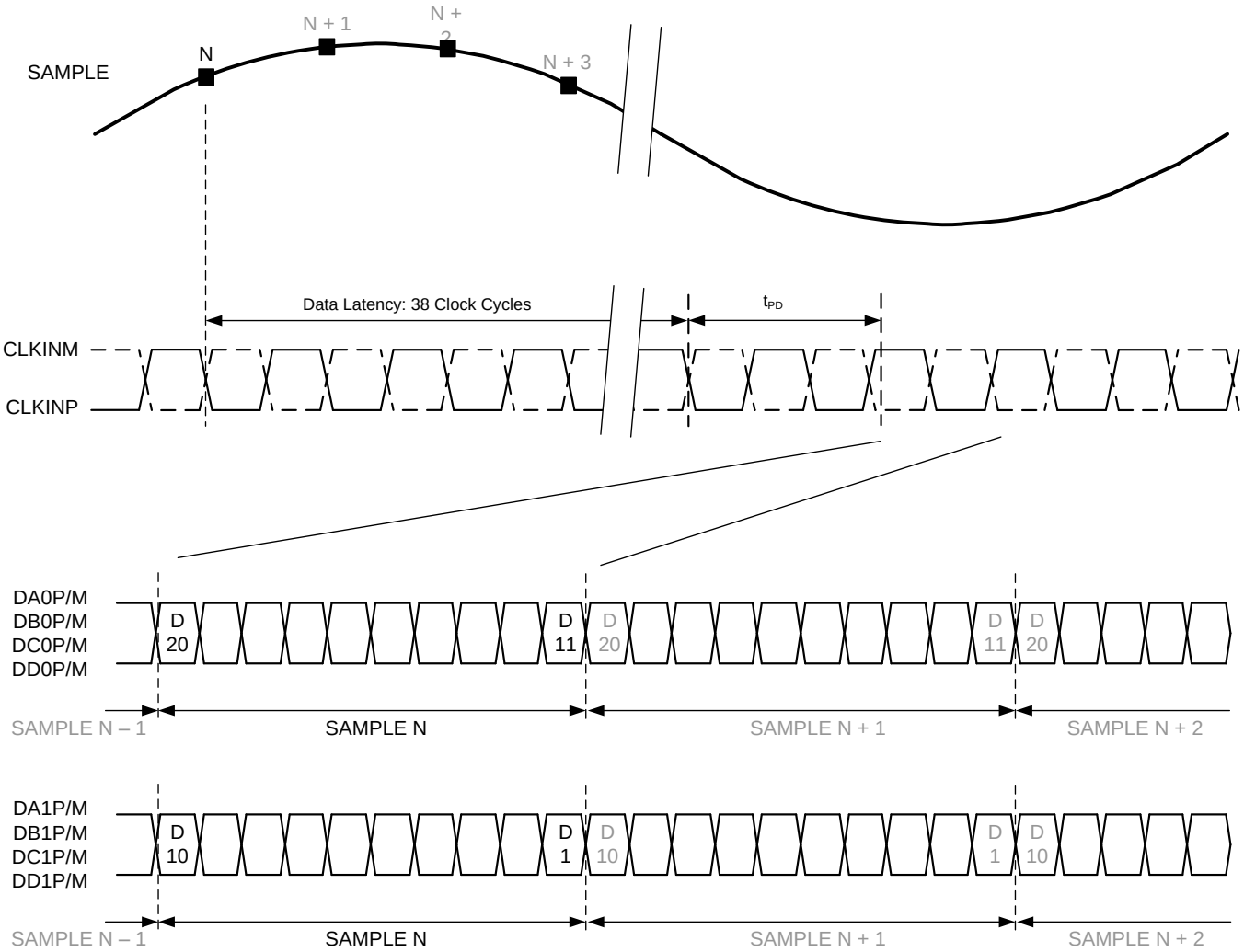


图 1. Reset Timing Diagram



A. t_{PD} is the propagation delay from sample clock input edge to serial data output transition

图 2. Timing Diagram: 250 MSPS Output Data Rate



B. t_{PD} is the propagation delay from sample clock input edge to serial data output transition

图 3. Timing Diagram: 500 MSPS Output Data Rate

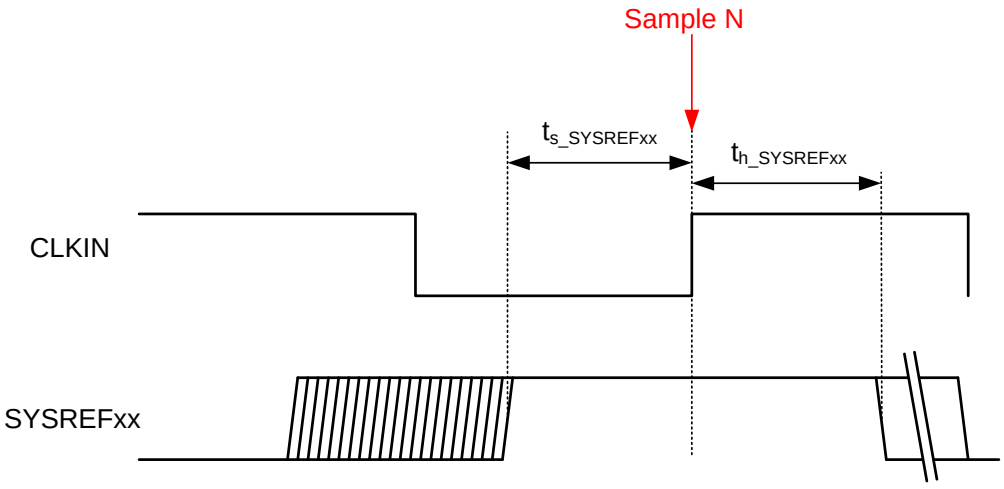


图 4. Timing Using SYSREF (Subclass 1)

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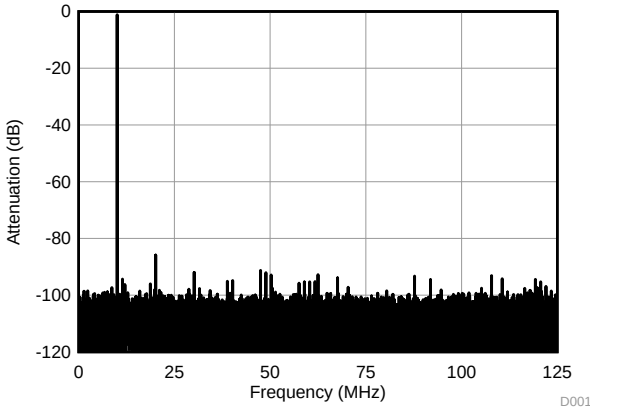
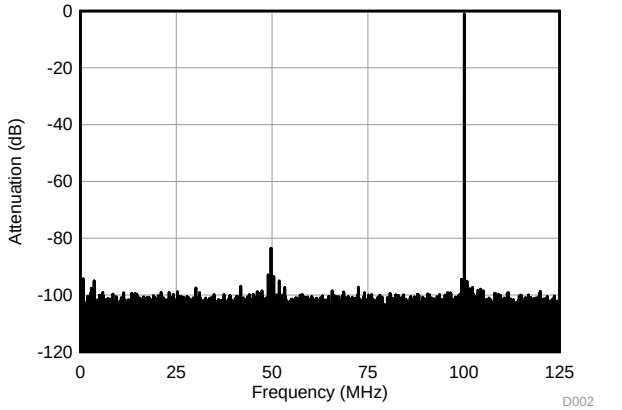
6.12 Typical Characteristics

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



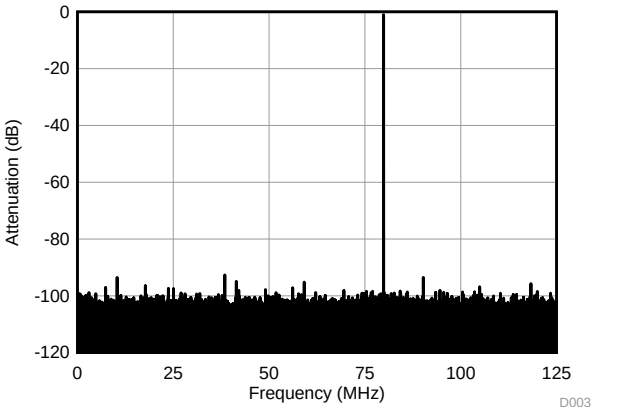
Fin = 10 MHz 1-lane 2x decimation Ain = –1 dBFS
SNR = 65.29 dBFS SFDR = 84.72 dBc

图 5. FFT 10 MHz



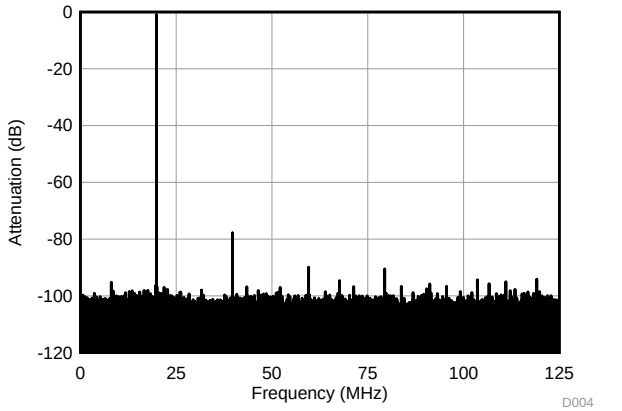
Fin = 100 MHz 1-lane 2x decimation Ain = –1 dBFS
SNR = 65.40 dBFS SFDR = 82.50 dBc

图 6. FFT 100 MHz



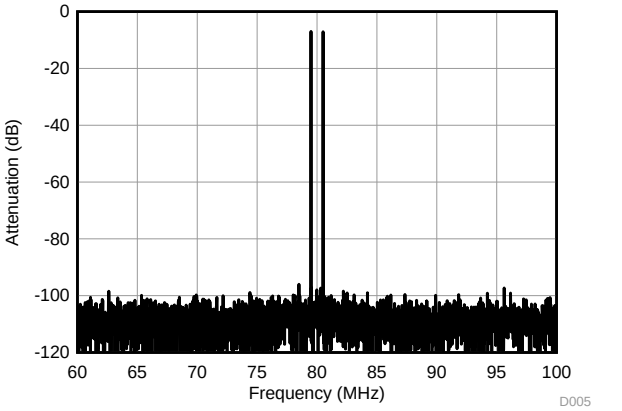
Fin = 170 MHz 1-lane 2x decimation Ain = –1 dBFS
SNR = 65.34 dBFS SFDR = 91.62 dBc

图 7. FFT 170 MHz



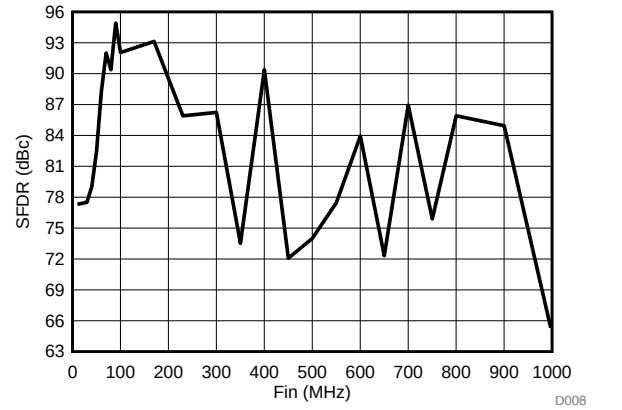
Fin = 230 MHz 1-lane 2x decimation Ain = –1 dBFS
SNR = 65.16 dBFS SFDR = 76.83 dBc

图 8. FFT 230 MHz



Fin = 230 MHz 1-lane 2x decimation Ain = –1 dBFS
SNR = 65.16 dBFS SFDR = 76.83 dBc

图 9. 2-Tone FFT

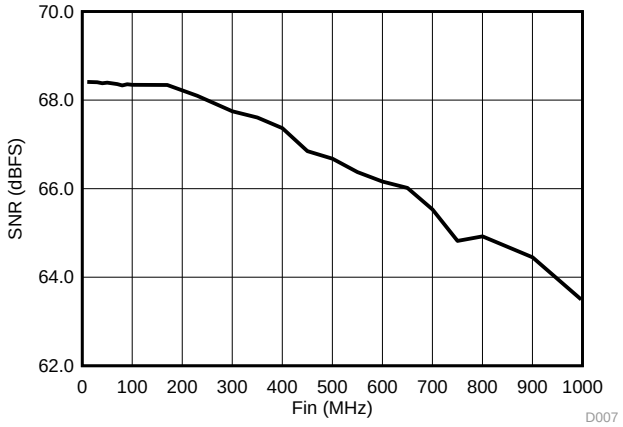


1-lane 2x decimation Ain = –1 dBFS

图 10. SFDR vs Frequency

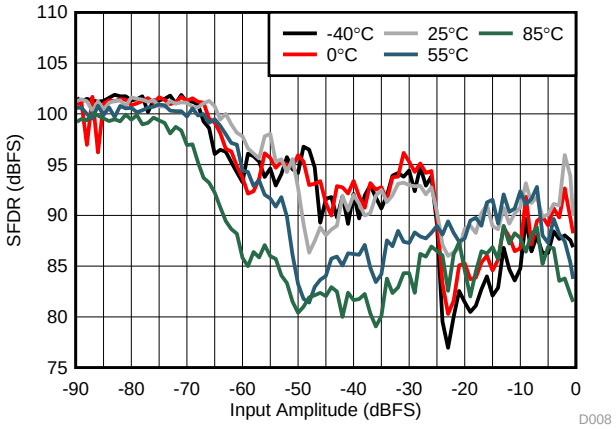
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



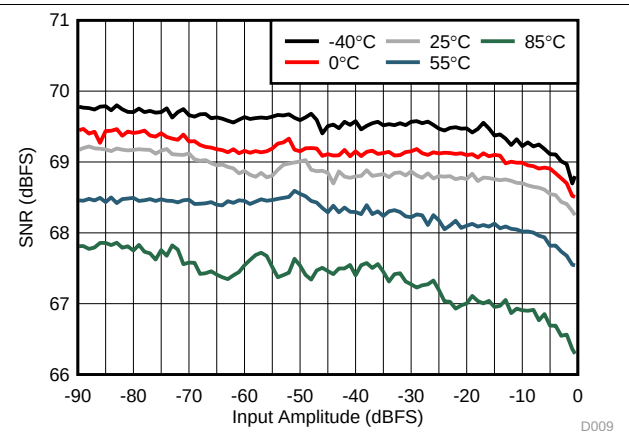
1-lane 2x decimation Ain = –1 dBFS

图 11. SNR vs. Frequency



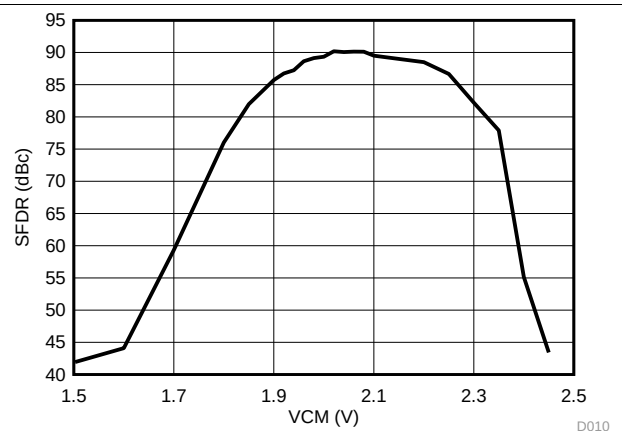
1-lane 2x decimation Fin = 170 MHz

图 12. SFDR vs. Amplitude



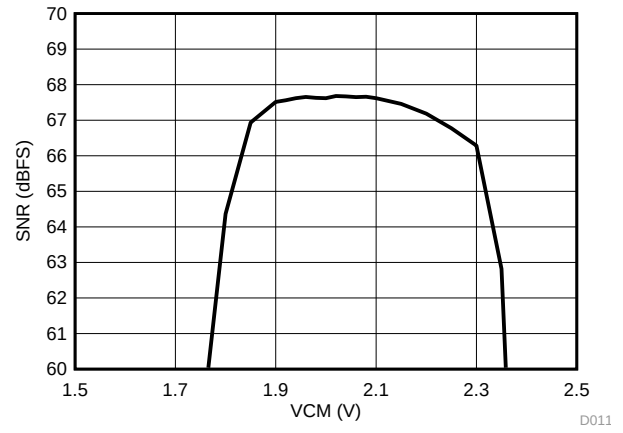
1-lane 2x decimation Fin = 170 MHz

图 13. SNR vs. Amplitude



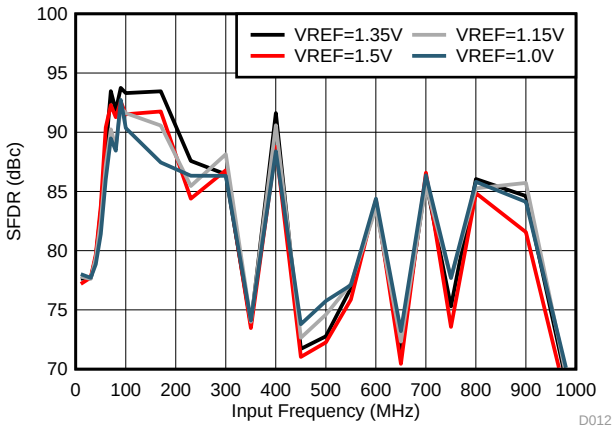
1-lane 2x decimation Fin = 170 MHz

图 14. SFDR vs. VCM



1-lane 2x decimation Fin = 170 MHz

图 15. SNR vs VCM



1-lane 2x decimation Ain = –1 dBFS

图 16. SFDR vs. VREF

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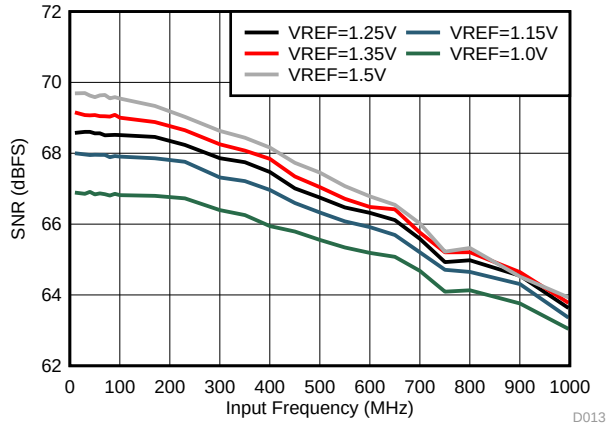
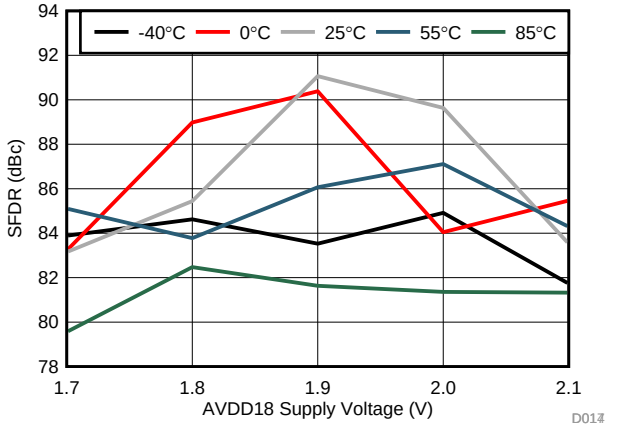
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



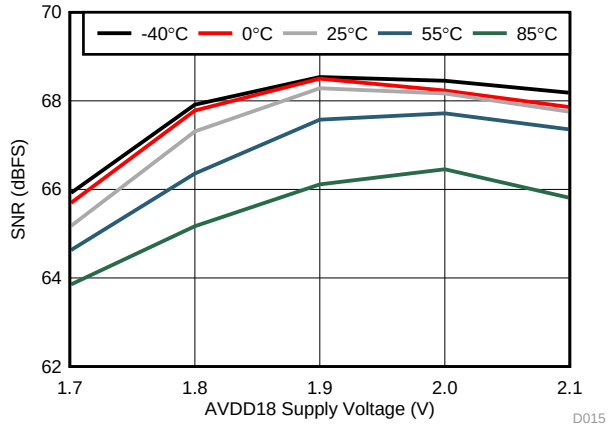
1-lane 2x decomposition Ain = –1 dBFS

图 17. SNR vs. VREF



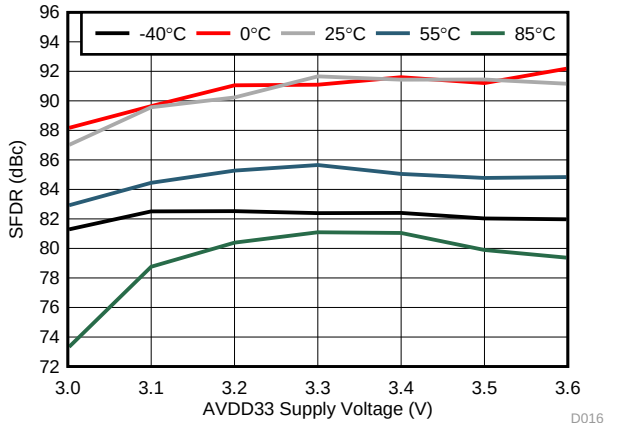
1-lane 2x decomposition Ain = –1 dBFS Fin = 170 MHz

图 18. SFDR vs. AVDD18



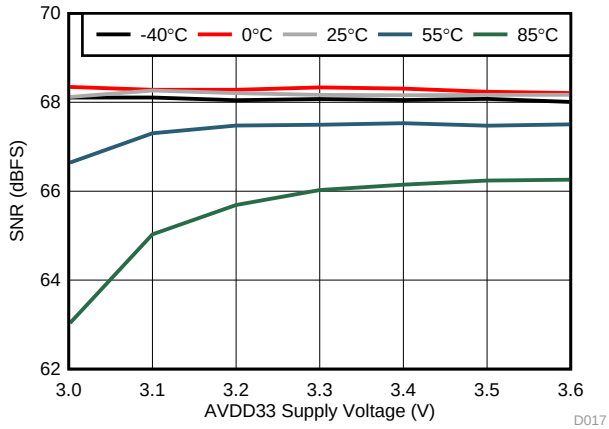
1-lane 2x decomposition Ain = –1 dBFS Fin = 170 MHz

图 19. SNR vs. AVDD18



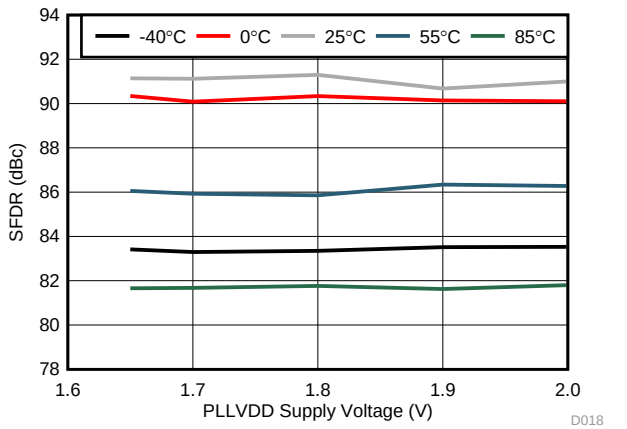
1-lane 2x decomposition Ain = –1 dBFS Fin = 170 MHz

图 20. SFDR vs. AVDD33



1-lane 2x decomposition Ain = –1 dBFS Fin = 170 MHz

图 21. SNR vs. AVDD33



1-lane 2x decomposition Ain = –1 dBFS Fin = 170 MHz

图 22. SFDR vs. PLLVDD

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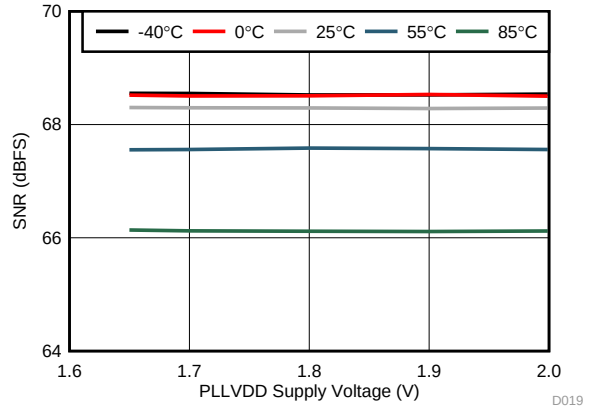
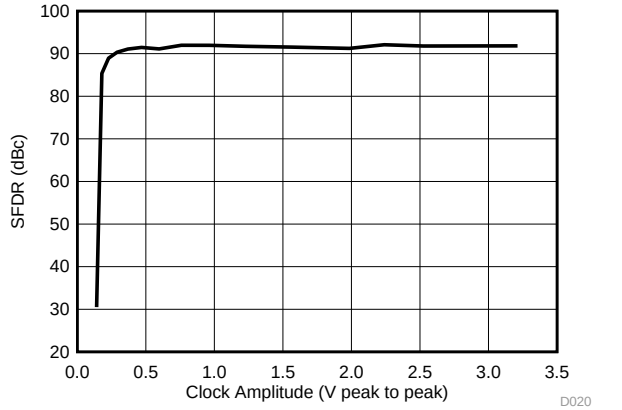
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



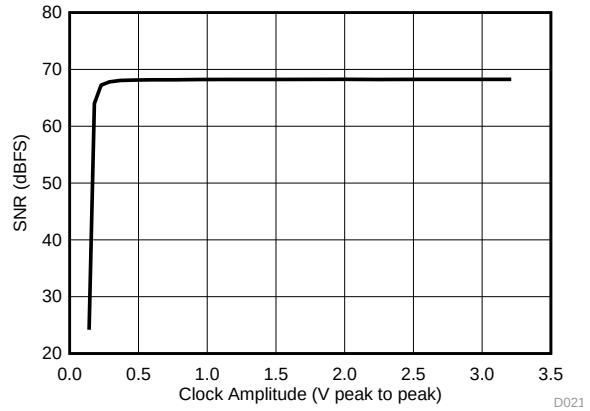
1-lane 2x decimation Ain = –1 dBFS Fin = 170 MHz

图 23. SNR vs PLLVDD



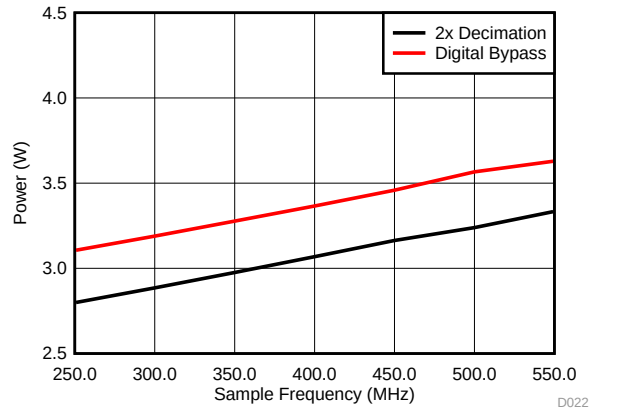
1-lane 2x decimation Ain = –1 dBFS Fin = 170 MHz

图 24. SFDR vs. Clock Amplitude



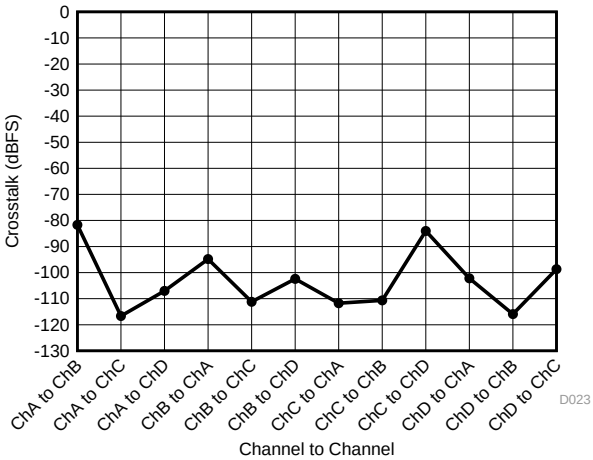
1-lane 2x decimation Ain = –1 dBFS Fin = 170 MHz

图 25. SNR vs. Clock Amplitude



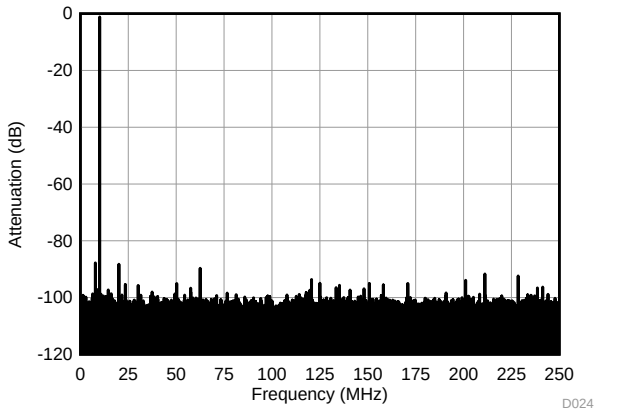
AVDD18 = 1.9 V AVDD33 = 3.3 V Other supplies = 1.8 V
Ain = –1 dBFS Fin = 170 MHz

图 26. Power vs Sample Frequency



1-lane 2x decimation Ain = –1 dBFS Fin = 170 MHz

图 27. Crosstalk by Channel



2-lane no decimation Ain = –1 dBFS Fin = 10 MHz
SNR = 65.27 dBFS SFDR = 86.63 dBc

图 28. FFT 10 MHz

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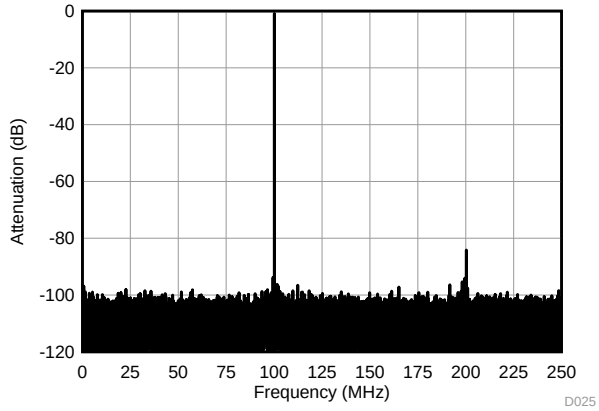
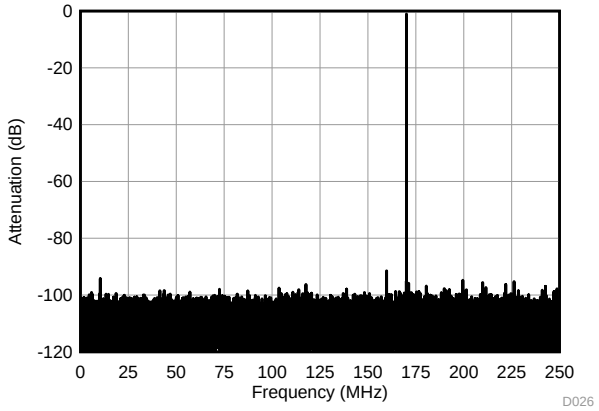
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



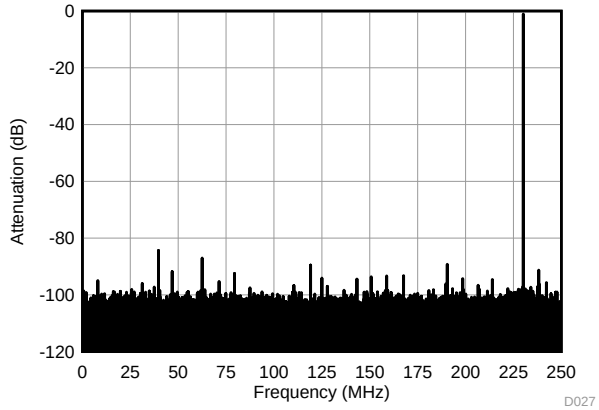
2-lane no decimation Ain = –1 dBFS Fin = 100 MHz
SNR = 65.41 dBFS SFDR = 83.25 dBc

图 29. FFT 100 MHz



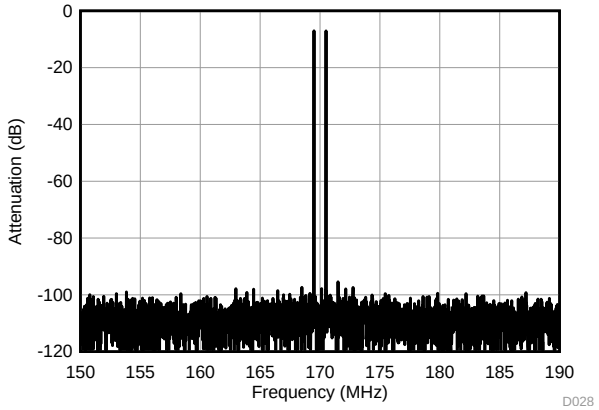
2-lane no decimation Ain = –1 dBFS Fin = 170 MHz
SNR = 65.26 dBFS SFDR = 90.42 dBc

图 30. FFT 170 MHz



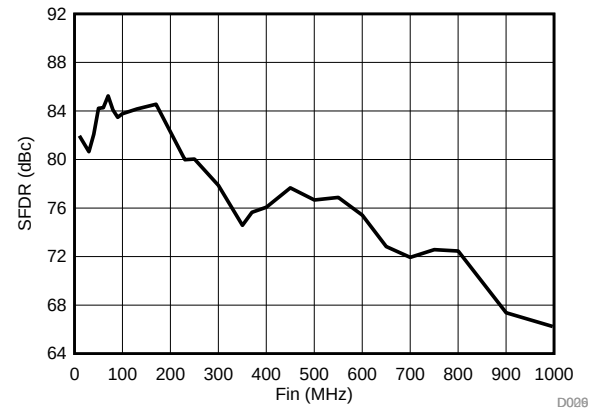
2-lane no decimation Ain = –1 dBFS Fin = 230 MHz
SNR = 64.91 dBFS SFDR = 83.29 dBc

图 31. FFT 230 MHz



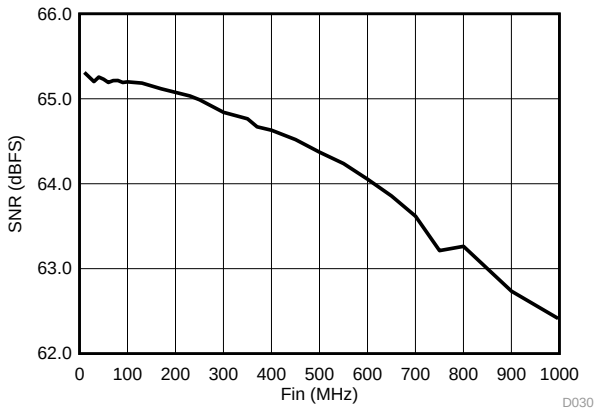
2-lane no decimation Ain = –1 dBFS
Fin = 170 MHz

图 32. 2-Tone FFT



2-lane no decimation Ain = –1 dBFS

图 33. SDFR vs Frequency

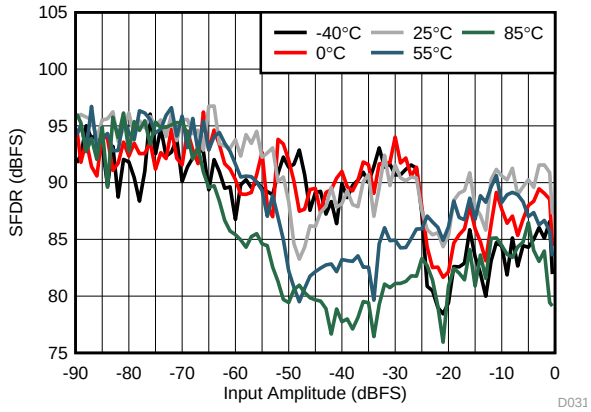


2-lane no decimation Ain = –1 dBFS

图 34. SNR vs Frequency

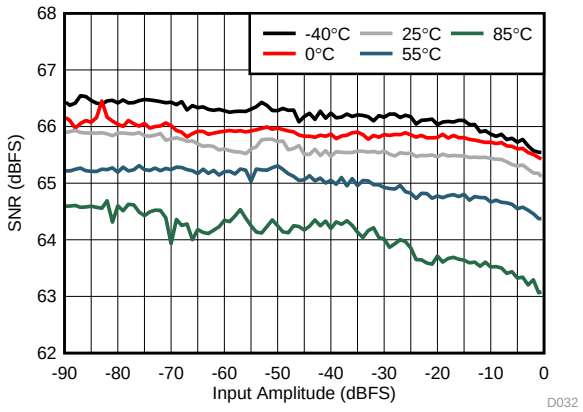
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



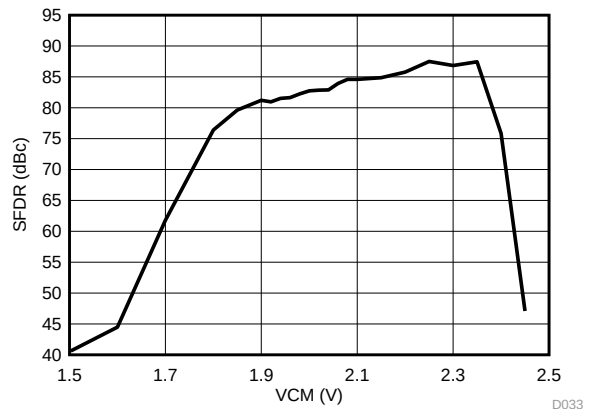
2-lane no decimation Fin = 170 MHz

图 35. SFDR vs Amplitude



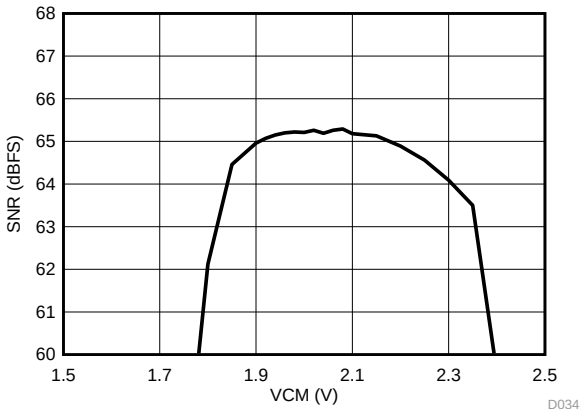
2-lane no decimation Fin = 170 MHz

图 36. SNR vs Amplitude



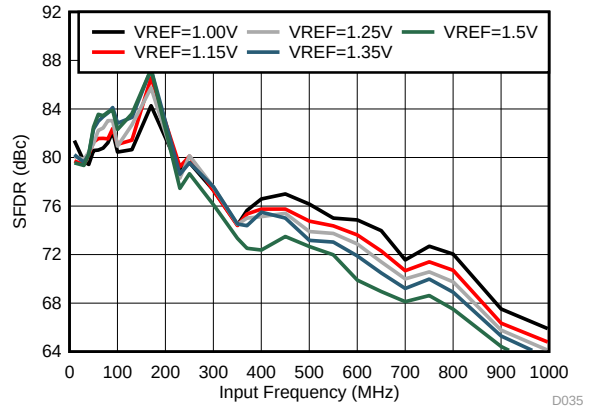
2-lane no decimation Fin = 170 MHz

图 37. SFDR vs VCM



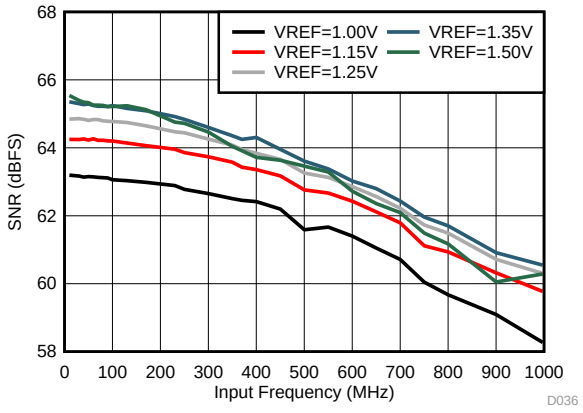
2-lane no decimation Fin = 170 MHz

图 38. SNR vs VCM



2-lane no decimation Ain = –1 dBFS

图 39. SFDR vs Input Frequency



2-lane no decimation Ain = –1 dBFS

图 40. SNR vs Input Frequency

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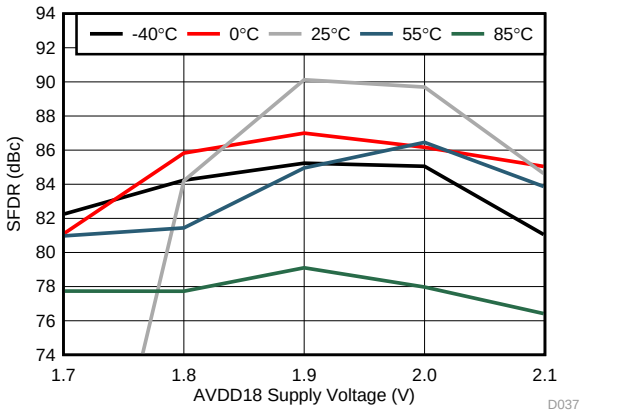
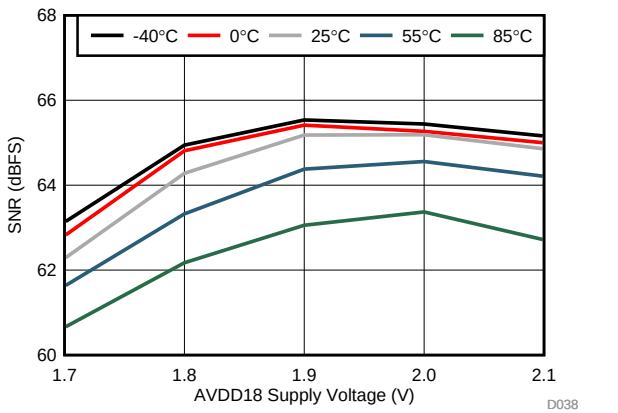
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



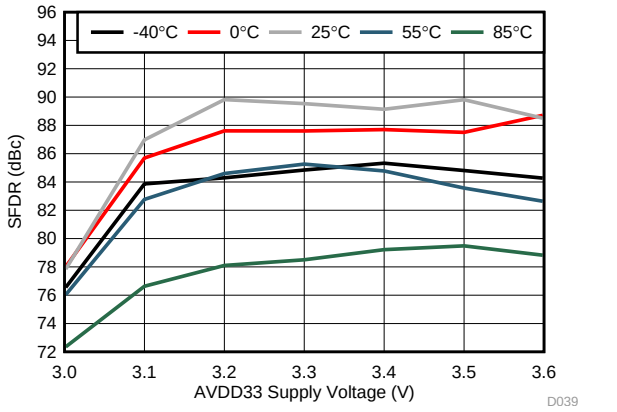
2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 41. SFDR vs AVDD18 Supply Voltage



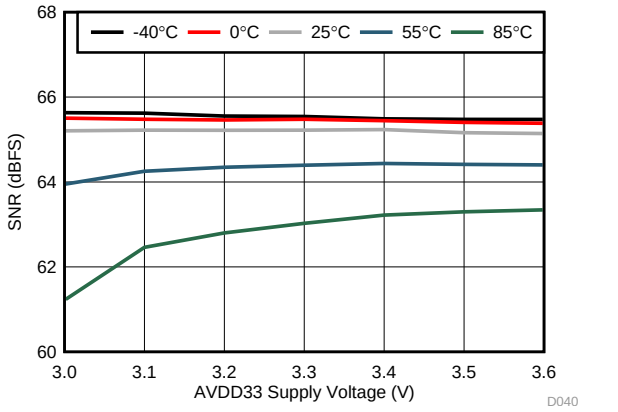
2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 42. SNR vs AVDD18 Supply Voltage



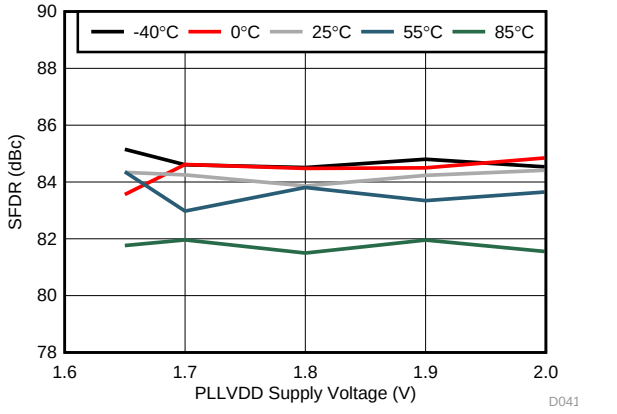
2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 43. SFDR vs AVDD33 Supply Voltage



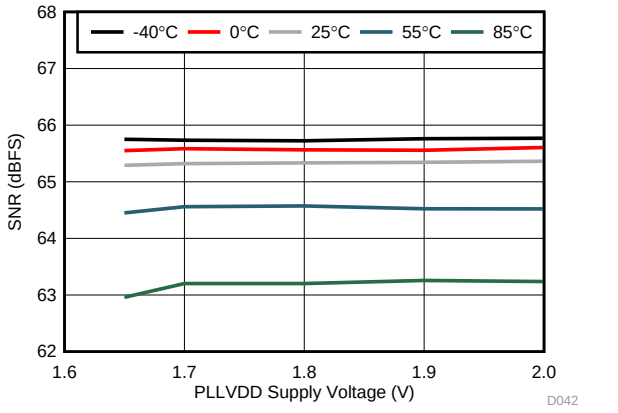
2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 44. SNR vs AVDD33 Supply Voltage



2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 45. SFDR vs PLLVDD Supply Voltage



2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 46. SNR vs PLLVDD Supply Voltage

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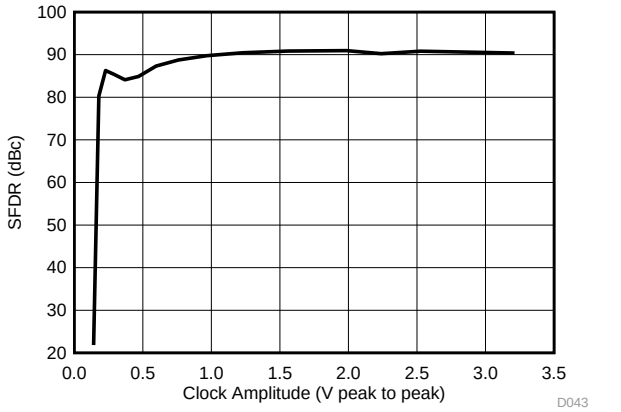
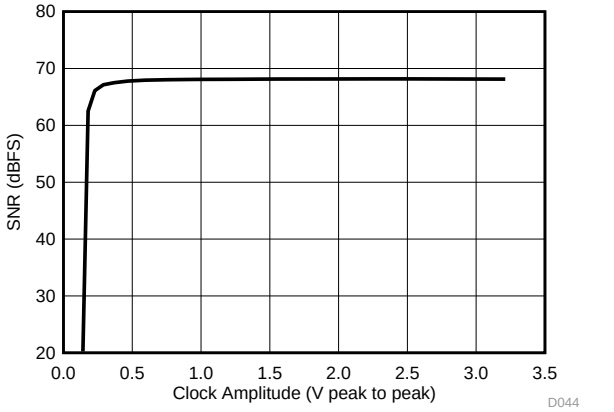
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



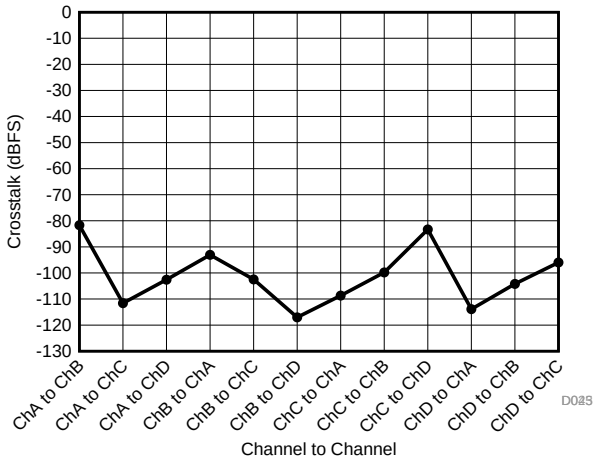
2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 47. SFDR vs Clock Amplitude



2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 48. SNR vs Clock Amplitude



2-lane no decimation Ain = –1 dBFS Fin = 170 MHz

图 49. Crosstalk by Channel

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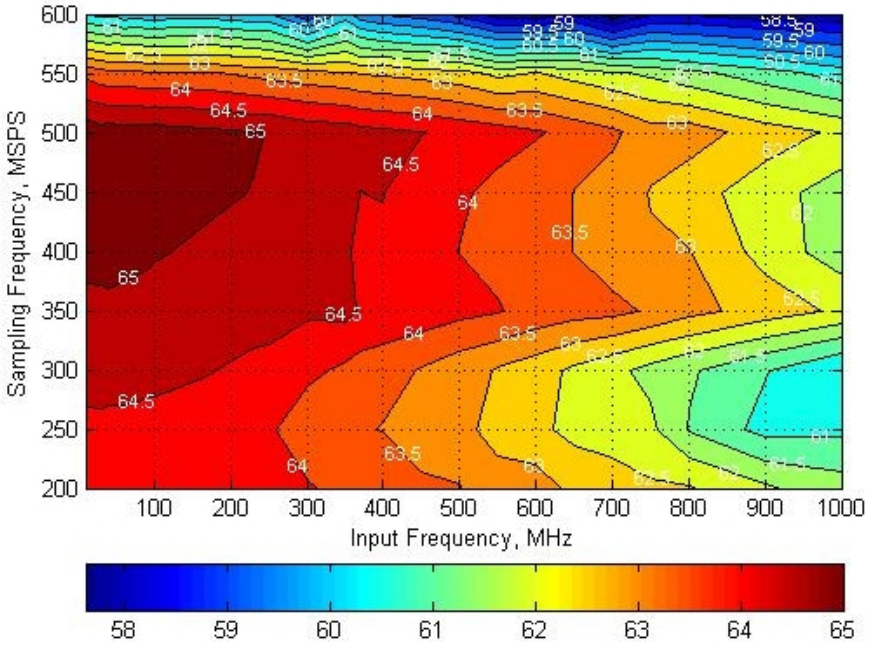
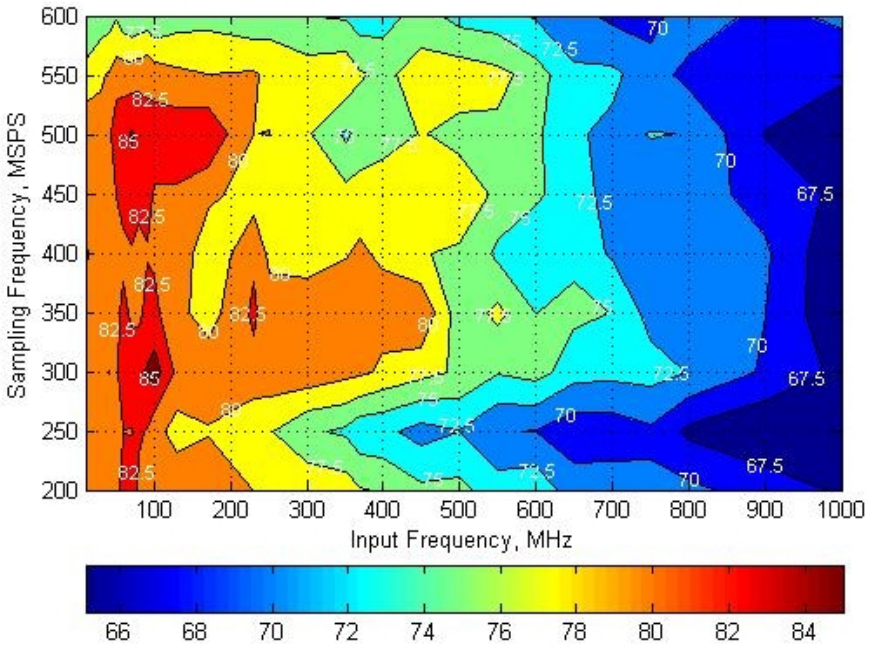
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



2lane no decimation

图 50. SNR Contour Plot

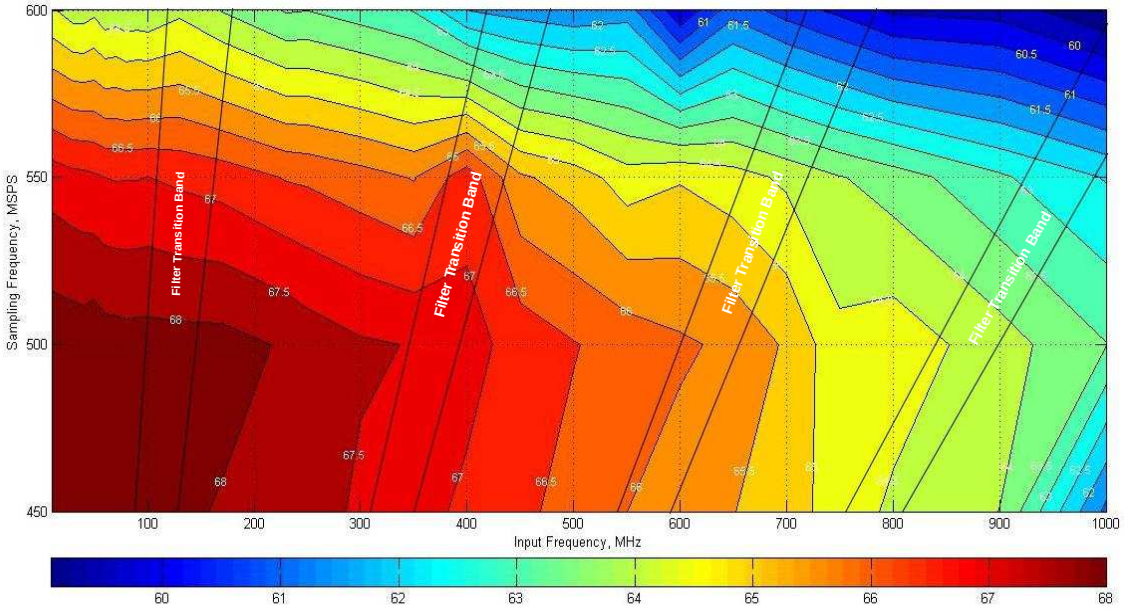


2lane no decimation

图 51. SFDR Contour Plot

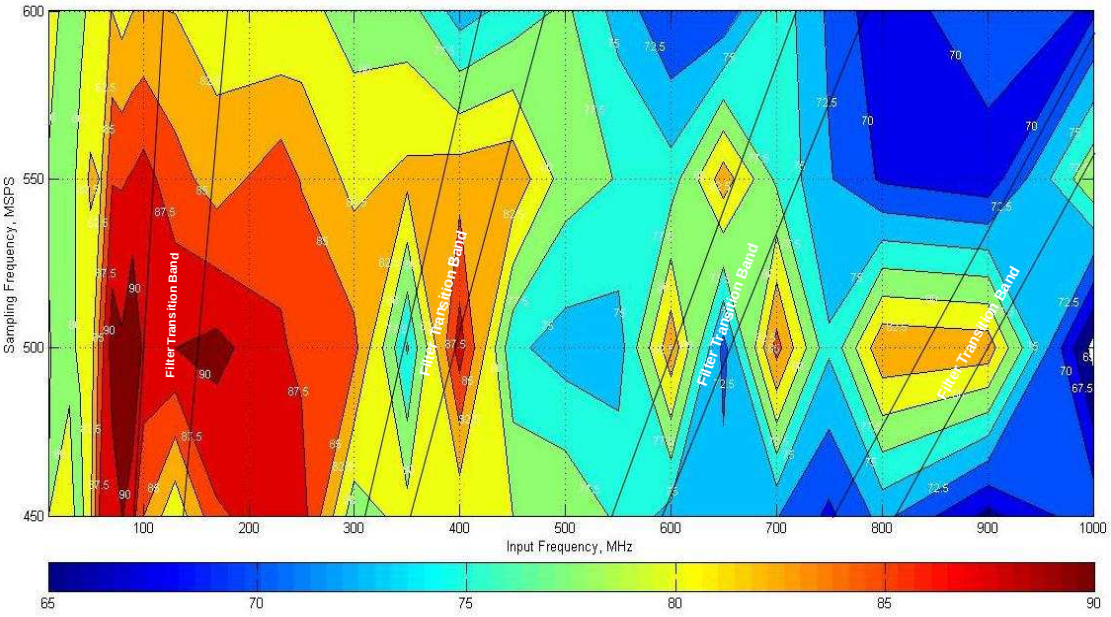
Typical Characteristics (接下页)

Typical values at T_A = 25°C, full temperature range is T_{MIN} = –40°C to T_{MAX} = 85°C, Device clock frequency = 500 MHz, Output sample data rate = 5Gbps, 50% Device clock duty cycle, AVDD33 = 3.3 V, AVDD18 = 1.9 V, AVDDC = 1.8 V, IOVDD = 1.8 V, PLLVDD = 1.8 V, DVDD = 1.8 V, –1 dBFS differential input, unless otherwise noted, FFT sample size = 32768.



1lane 2x decimation

图 52. SNR Contour Plot



1lane 2x decimation

图 53. SFDR Contour Plot

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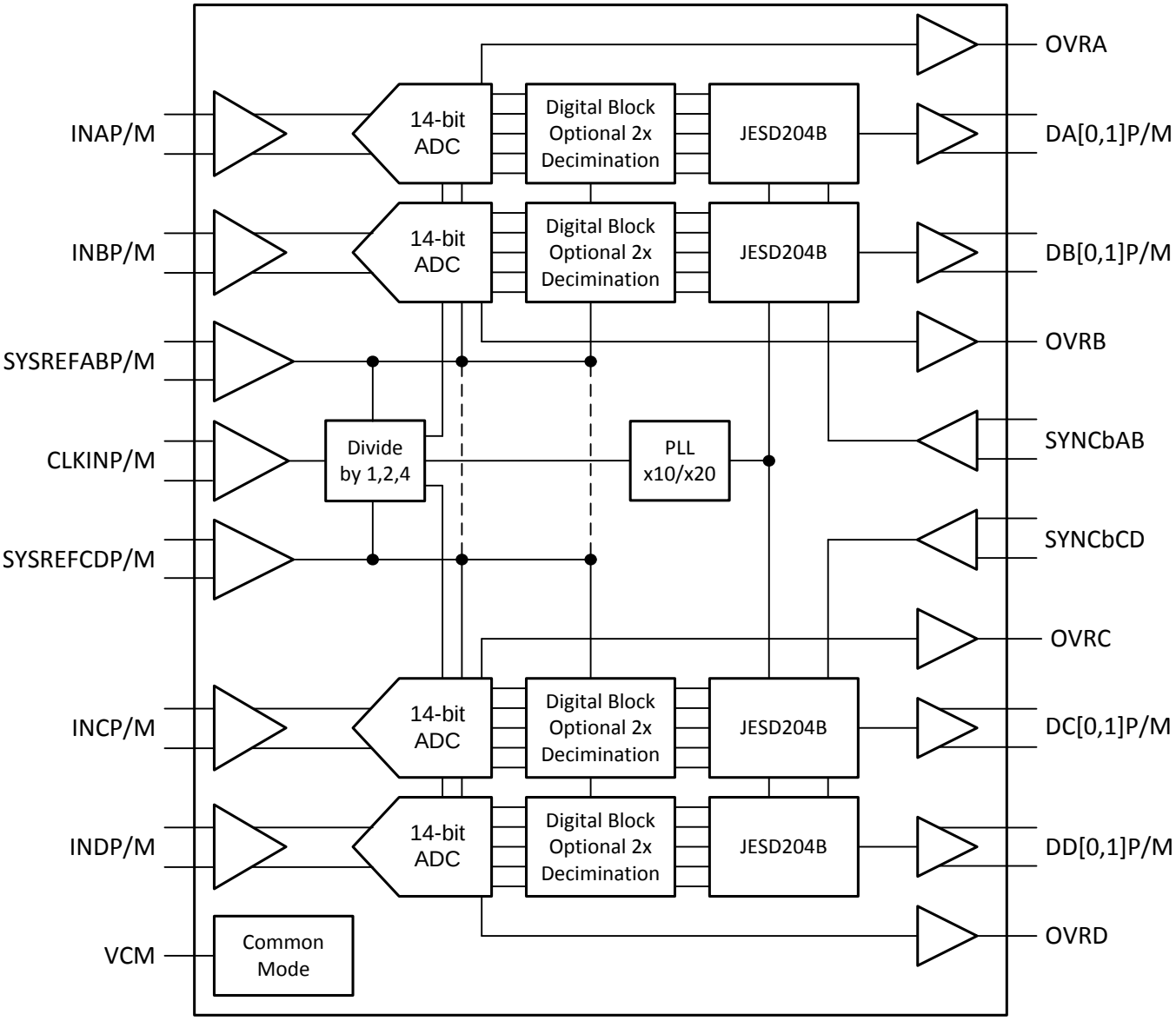
7 Detailed Description

7.1 Overview

The ADS54J54 is a low power, wide bandwidth 14-bit 500 MSPS quad channel ADC. It supports the JESD204B serial interface with data rates up to 5.0 Gbps supporting 1 or 2 lanes per channel. The buffered analog input provides uniform input impedance across a wide frequency range while minimizing sample-and-hold glitch energy. A sampling clock divider allows more flexibility for system clock architecture design. The ADS54J54 provides excellent SFDR over a large input frequency range with low power consumption.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Decimation by 2 (250 MSPS Output)

Each channel has a digital filter in the data path as shown in 图 54. The filter can be programmed as a low-pass or high-pass filter and the normalized frequency response of both filters is shown in 图 55.

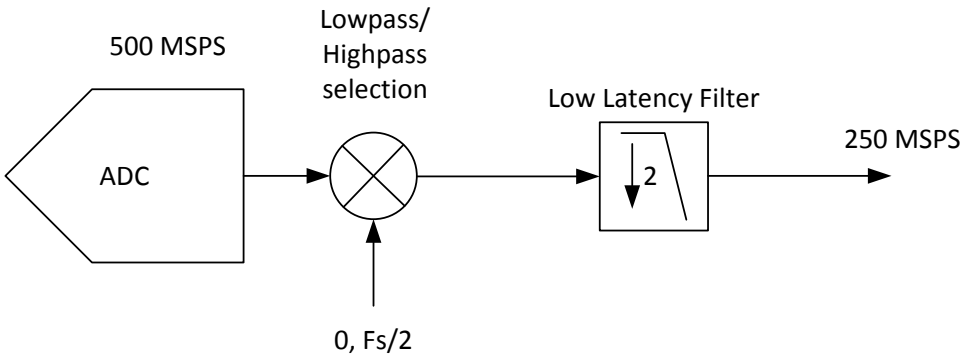


图 54. 2x Decimation Filter

The decimation filter response has a 0.1-dB pass band ripple with approximately 41% pass-band bandwidth. The stop-band attenuation is approximately 40 dB.

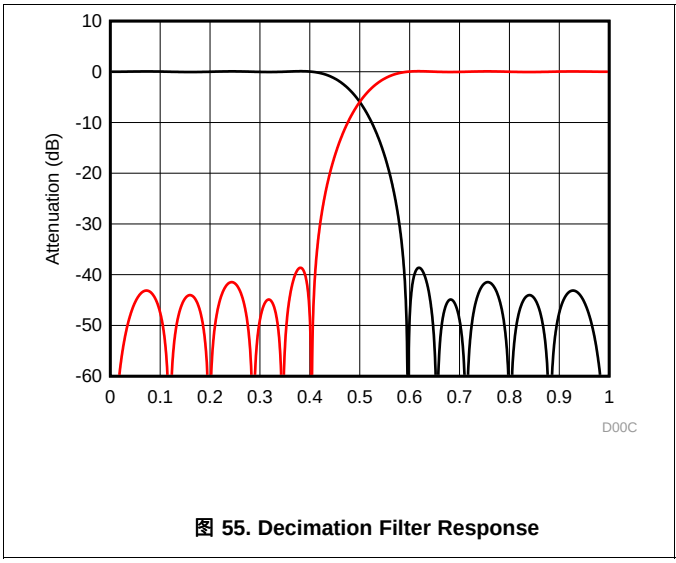


图 55. Decimation Filter Response

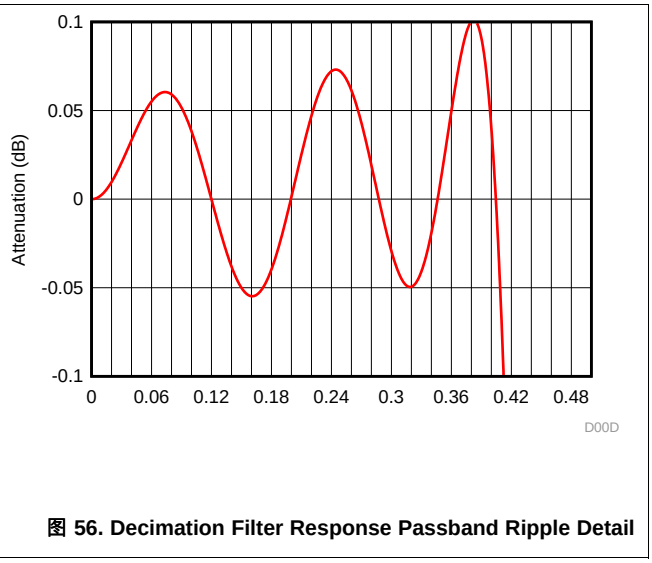


图 56. Decimation Filter Response Passband Ripple Detail

7.3.2 Over-Range Indication

The ADS54J54 provides a fast over-range indication on the OVRA, OVRB, OVRC, and OVRD pins. The fast OVR is triggered if the input voltage exceeds the programmable over-range threshold and is output after just 6 clock cycles, enabling a quicker reaction to an over-range event. The OVR threshold can be configured using SPI register writes.

The input voltage level at which the overload is detected is referred to as the threshold and is programmable using the over-range threshold bits.

The threshold at which fast OVR is triggered is (full-scale × [the decimal value of the FAST OVR THRESH bits] / 8). After reset, the default value of the over-range threshold is set to 7 (decimal), which corresponds to a threshold of 1.12 dB below full scale (20 × log(7/8)).

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表 1. Fast Over Range Threshold Settings

OVR Setting (decimal)	OVR Threshold (dBFS)
1	–18.1
2	–12.0
3	–8.5
4	–6.0
5	–4.1
6	–2.5
7 (default)	–1.1

Because the fast over-range indicator is single-ended LVCMOS logic, the ADS54J54 device can be configured through the SPI register write to keep the over-range indicator asserted high for an extra one, two, or four clock cycles. This longer assertion of the signal ensures the processor can capture the over-range event.

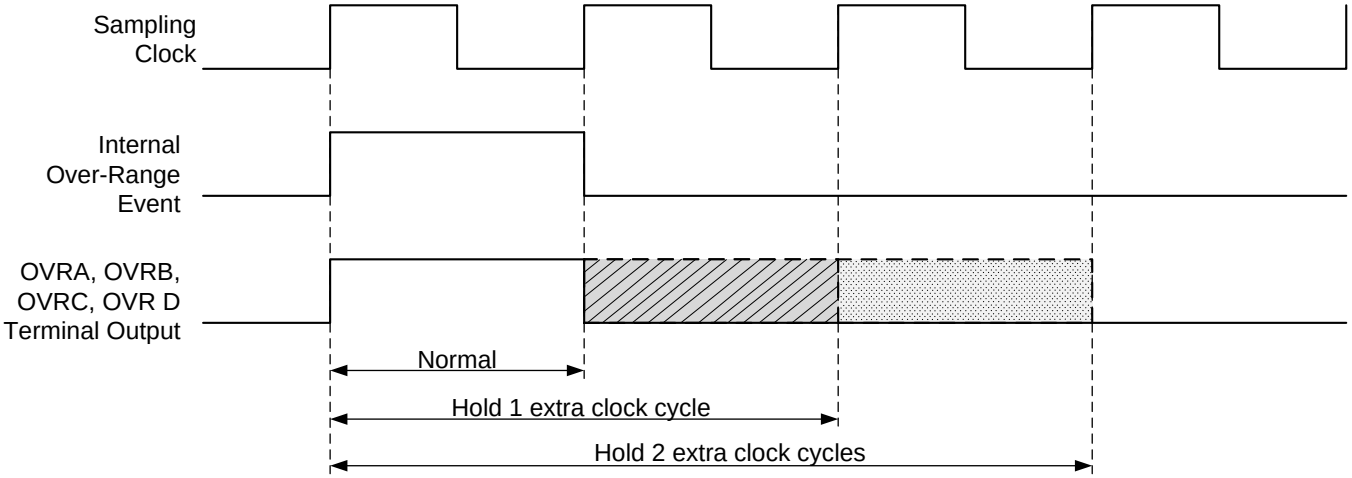

图 57. Fast Over Range Output Timing

The ADS54J54 device also provides the fast over-range indication bit in the JESD204B output data stream.

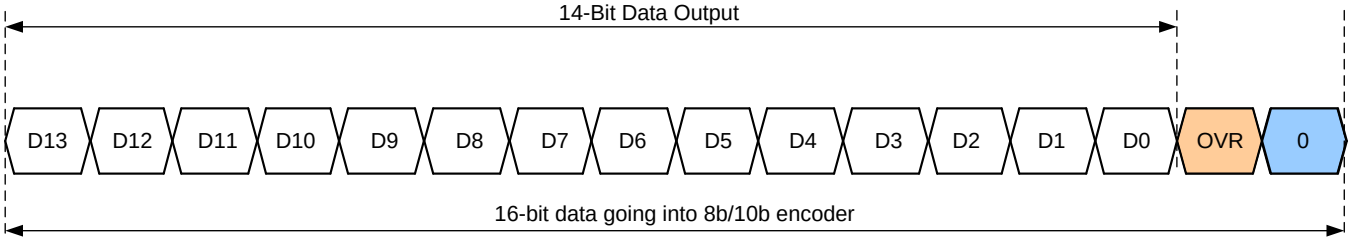

图 58. Sample Data and Status Bit Format

7.3.3 JESD204B Interface

The ADS54J54 supports device subclass 1 with a maximum output data rate of 5 Gbps for each serial transmitter. It allows independent JESD204B format configuration for channel A and B and channel C and D.

An external SYSREF signal is used to align all internal clock phases and the local multi-frame clock to a specific sampling clock edge. This allows synchronization of multiple devices in a system and minimizes timing and alignment uncertainty. SYNCbAB input is used to control all the JESD204B SerDes blocks for channel A and B while SYNCbCD is used to control channel C and D. If the same LMFS configuration is used for all four channels, the SYNCbAB and SYNCbCD signals can be tied together externally and driven from the same source.

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Depending on the channel output data rate, the JESD204B output interface can be operated with either 1 or 2 lanes per single channel. The JESD204B setup and configuration of the frame assembly parameters are controlled via SPI interface.

The JESD204B transmitter block consists of the transport layer, the data scrambler and the link layer. The transport layer maps the channel output data into the selected JESD204B frame data format and manages if the channel output data or test patterns are being transmitted. The link layer performs the 8b/10b data encoding as well as the synchronization and initial lane alignment using the SYNCb input signal. Optionally, data from the transport layer can be scrambled.

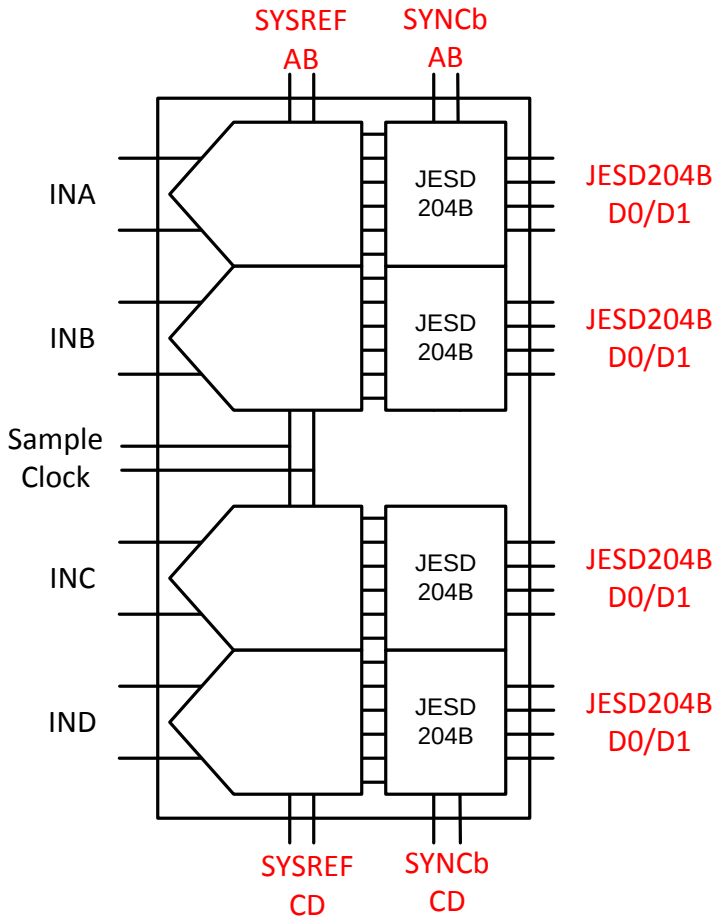

图 59. JESD204B Lane Assignment

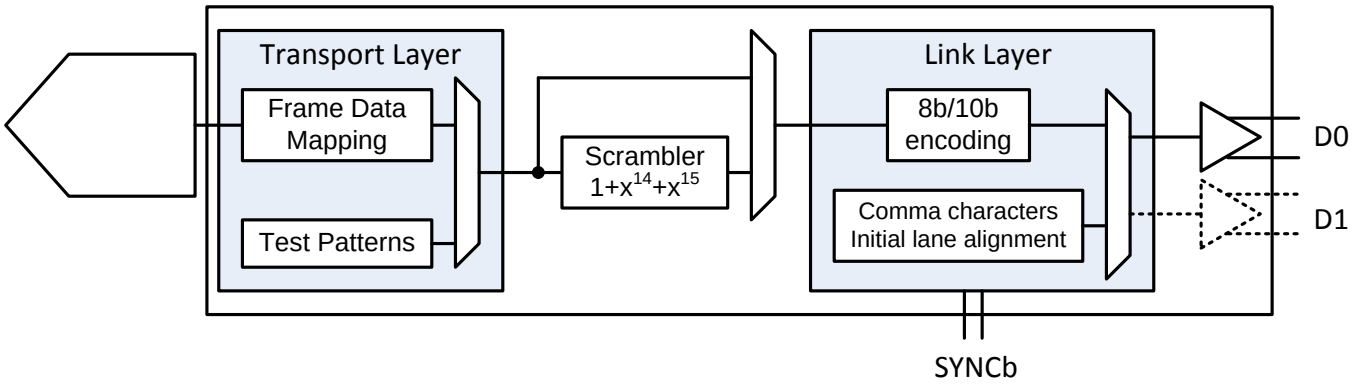

图 60. JESD204B Block

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7.3.3.1 JESD204B Initial Lane Alignment (ILA)

The ILA process is started by the receiving device by deasserting the SYNCb signal. Upon detecting a logic low on the SYNCbAB input pins, the ADS54J54 device starts transmitting comma (K28.5) characters on channels A and B to establish code group synchronization. Upon detecting a logic high on the SYNCbCD input pins, the ADS54J54 device starts transmitting comma (K28.5) characters on channels C and D to establish code group synchronization.

After synchronization is completed, the receiving device asserts the SYNCb signal and the ADS54J54 starts the ILA sequence with the next local multi-frame clock boundary. The ADS54J54 device transmits 4 multi-frames each containing K frames (K is SPI programmable). Each of the multi-frames contains the frame start and end symbols and the second multi-frame also contains the JESD204 link configuration data.

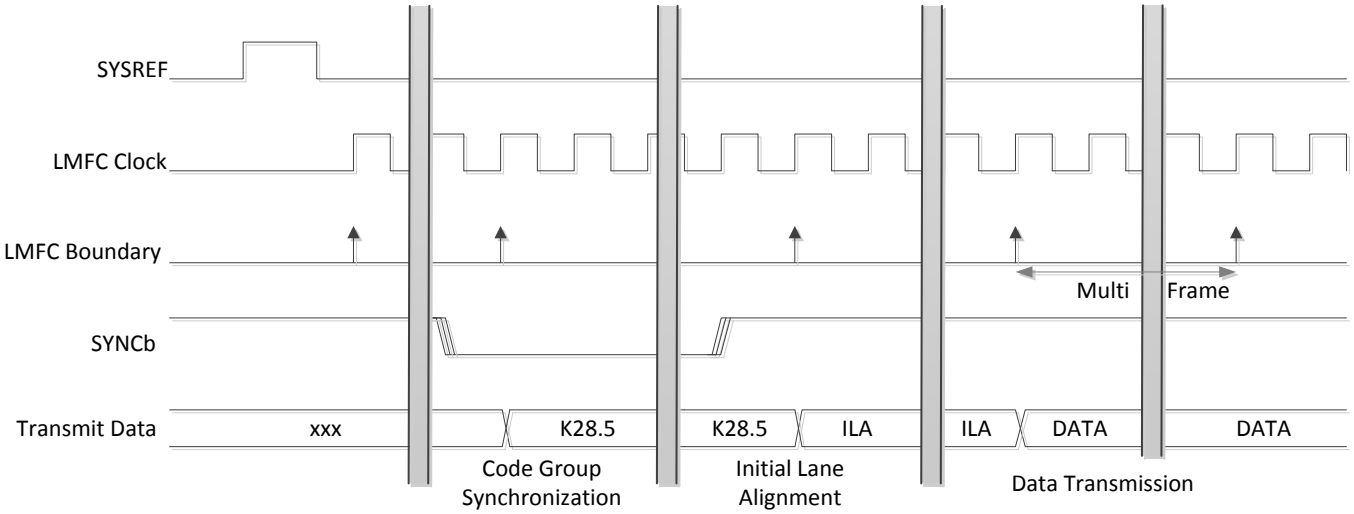

图 61. Initial Lane Assignment Format

7.3.3.2 JESD204B Test Patterns

There are three different test patterns available in the transport layer of the JESD204B interface. The ADS54J54 supports a RAMP, 1555/2AAA and different PRBS patterns. They can be enabled through SPI register write and are located in address 0x1D and 0x32/33.

7.3.3.3 JESD204B Frame Assembly

The JESD204B standard defines the following parameters:

- L = number of lanes per link
- M = number of converters for device
- F = number of octets per frame clock period
- S = number of samples per frame
- HD = high density mode

The ADS54J54 supports independent configuration of the JESD204B format for channel A and B and channel C and D. 表 2 lists the available JESD204B formats and valid ranges for the ADS54J54. The ranges are limited by the SerDes line rate and the maximum channel sample frequency.

表 2. Permissible LMFS Settings

L	M	F	S	HD	Max Channel Output Rate (MSPS)	Max f_{SerDes} (Gsps)
8	4	1	1	1	500	5.0
4	4	2	1	0	250	5.0

The detailed frame assembly is shown in 表 3.

表 3. LMFS Data Formats

	LMFS = 8411				LMFS = 4421					
Lane DA0	A0[13:6]	A1[13:6]	A2[13:6]	A3[13:6]	A0[13:6]	A0[5:0], 00	A1[13:6]	A1[5:0], 00	A2[13:6]	A2[5:0], 00
Lane DA1	A0[5:0], 00	A1[5:0], 00	A2[5:0], 00	A3[5:0], 00						
Lane DB0	B0[13:6]	B1[13:6]	B2[13:6]	B3[13:6]	B0[13:6]	B0[5:0], 00	B1[13:6]	B1[5:0], 00	B2[13:6]	B2[5:0], 00
Lane DB1	B0[5:0], 00	B1[5:0], 00	B2[5:0], 00	B3[5:0], 00						
Lane DC0	C0[13:6]	C1[13:6]	C2[13:6]	C3[13:6]	C0[13:6]	C0[5:0], 00	C1[13:6]	C1[5:0], 00	C2[13:6]	C2[5:0], 00
Lane DC1	C0[5:0], 00	C1[5:0], 00	C2[5:0], 00	C3[5:0], 00						
Lane DD0	D0[13:6]	D1[13:6]	D2[13:6]	D3[13:6]	D0[13:6]	D0[5:0], 00	D1[13:6]	D1[5:0], 00	D2[13:6]	D2[5:0], 00
Lane DD1	D0[5:0], 00	D1[5:0], 00	D2[5:0], 00	D3[5:0], 00						

7.3.4 SYSREF Clocking Schemes

Periodic: The SYSREF signal is always on. This mode is supported, but not recommended as the continuous SYSREF signal appears like an additional clock input, which can cause clock mixing spurs in the channel output spectrum.

Gapped-Periodic (recommended): A periodic SYSREF signal is presented to the ADS54J54 SYSREF inputs for a very short period of time. This configuration requires a DC-coupled SYSREF connection for proper operation. Most of the time the SYSREF signal is in a logic-low state, and thus cannot cause any glitches and spurs in the channel output spectrum.

Pulse/One Shot (recommended): A single SYSREF reset pulse is used to synchronize the ADS54J54. The ADS54J54 device requires a minimum of 3 SYSREF pulses to complete the synchronization phase. The SYSREF signal is in a logic-low state most of the time, and thus cannot cause any glitches and spurs in the channel output spectrum. Special attention should be given to ensure the single pulse meets required the SYSREF input setup and hold time.

7.3.5 Split-Mode Operation

The ADS54J54 provides several different options to interface it to the digital processor or processors. If the ADS54J54 device is operated in split sampling rate (2 channels at 500-MSPS output rate and 2 channels at 250-MSPS output rate), then it requires dual SYSREF (SYSREFAB and SYSREFCD) and dual SYNC (SYNCbAB and SYNCbCD).

Subclass 1 – Deterministic Latency: The device clock and synchronous SYSREF signal are provided by the timing unit to the ADS54J54 and the processor. The processor controls the SYNCb input signals for the JESD204B state machine for all four channels. In case the ADS54J54 is connected to two different processors, the differential SYNCb inputs of the ADS54J54 can be configured to two single-ended inputs where each pin controls the JESD204B state machine of the two corresponding channels.

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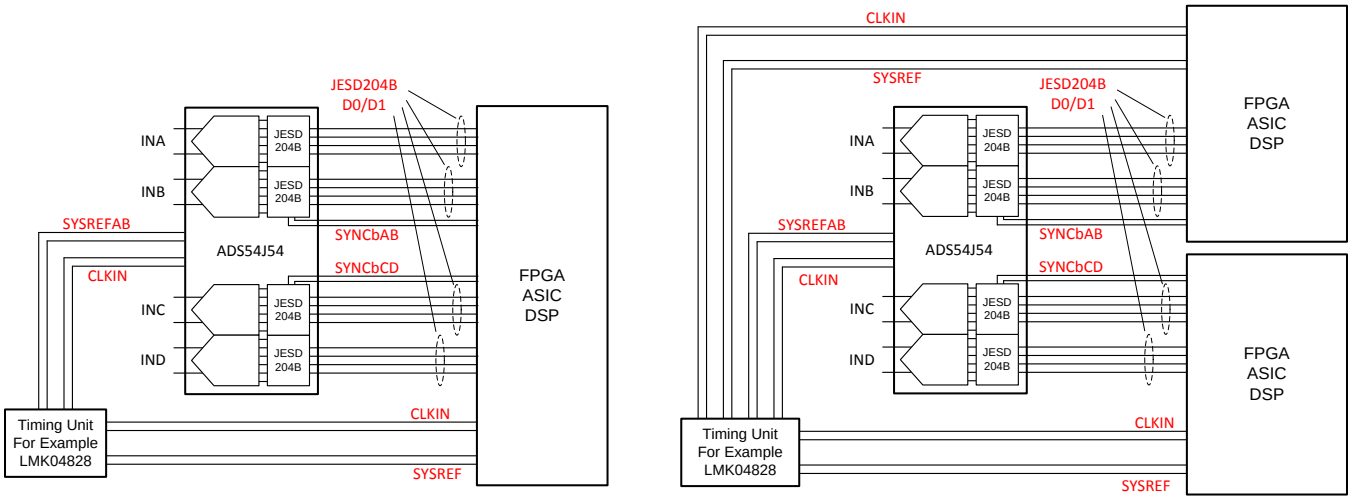

图 62. Four Channel and Dual Two Channel Usage

Split Mode Operation: If the ADS54J54 device is operated with 2-channel output at 500 MSPS and 2-channel output at 250 MSPS, then dual SYSREF (SYSREFAB for channel A and B, SYSREFCD for channel C and D) as well as dual SYNC (SYNCbAB for channel A and B, SYNCbCD for channel C and D) is required to ensure normal operation because the JESD204B link configuration is different for the two channel pairs.

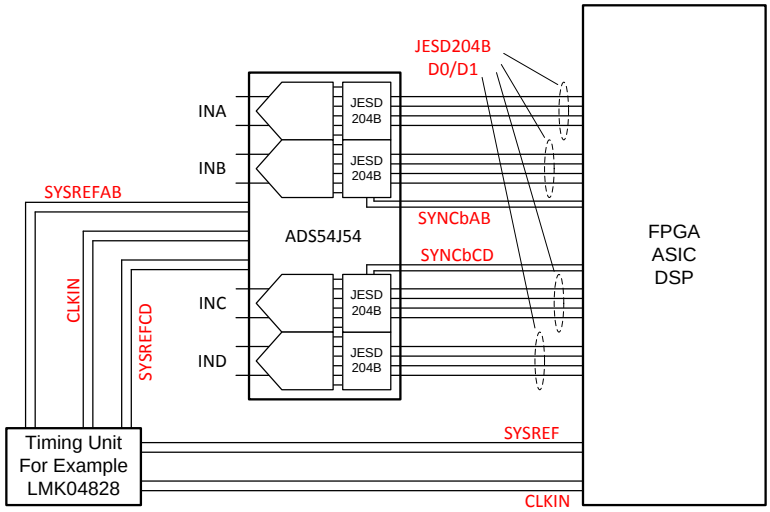

图 63. Dual SYSREF Usage

7.3.6 Eye Diagram Information

图 64 and 图 65 is the measured eye diagram at 2.5 and 5 Gbps output data rate, respectively. These are overlaid with the JESD204B LV-OIF-6G-SR specification.

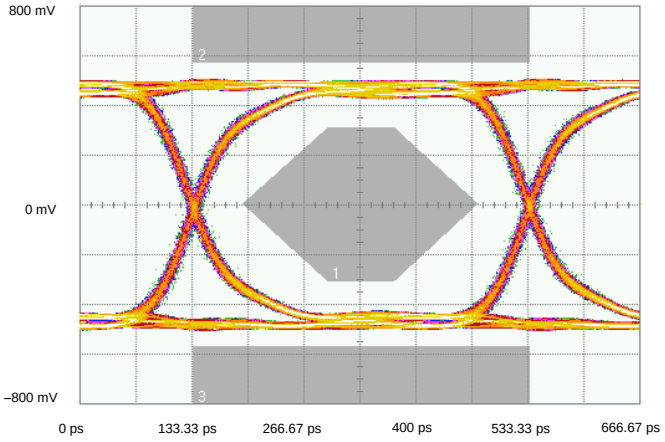

图 64. 2.5 Gbps Eye Diagram

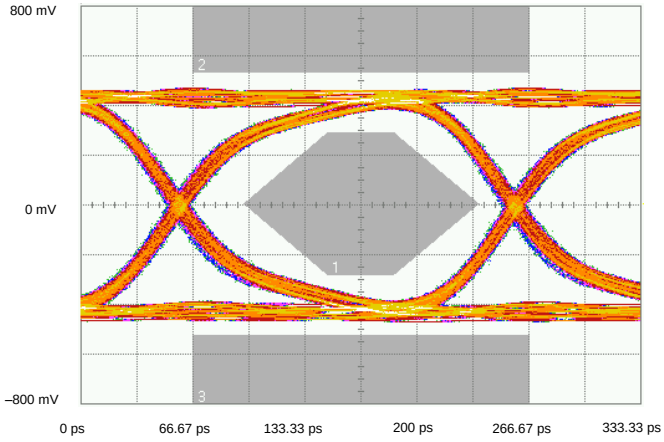

图 65. 5.0 Gbps Eye Diagram

7.3.7 Analog Inputs

The ADS54J54 analog signal inputs are designed to be driven differentially. The analog input pins have internal analog buffers that drive the sampling circuit. As a result of the analog buffer, the input pins present a high-impedance input across a wide frequency range to the external driving source, which enables great flexibility in the external analog filter design as well as excellent 50-Ω matching for RF applications. The buffer also helps isolate the external driving circuit from the internal switching currents of the sampling circuit, which results in a more constant SFDR performance across input frequencies.

The common-mode voltage of the signal inputs is internally biased to 2 V using 500-Ω resistors, which allows for AC coupling of the input drive network. Each input pin (INP, INM) must swing symmetrically between (VCM + 0.3125 V) and (VCM – 0.3125 V), resulting in a 1.25-Vpp (default) differential input swing. The input sampling circuit has a 3-dB bandwidth that extends up to 900 MHz.

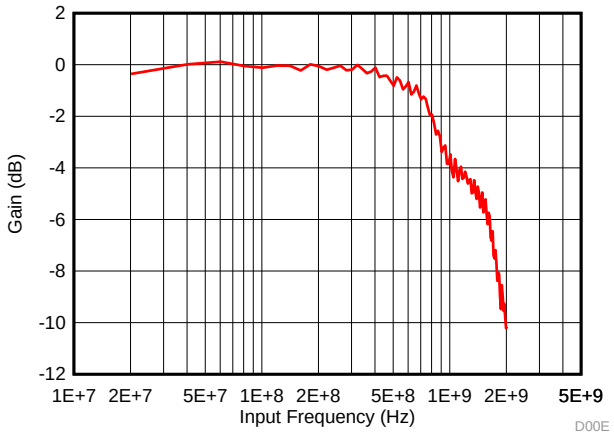

图 66. Normalized Input Bandwidth

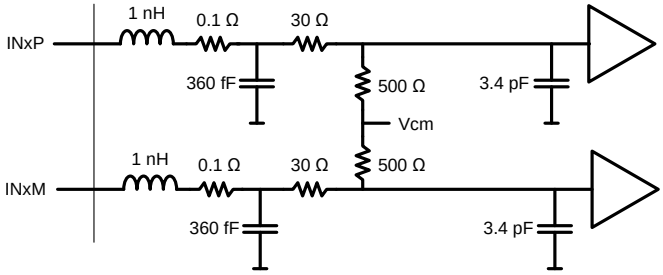

图 67. Equivalent Analog Input Circuit

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7.3.8 Clock Inputs

The ADS54J54 clock input can be driven differentially with a sine wave or LVPECL source with little or no difference in performance. The common mode voltage of the clock input is set to 0.9 V using internal 2-kΩ resistors. This allows for AC coupling of the clock inputs. The termination resistors should be placed as close as possible to the clock inputs in order to minimize signal reflections and jitter degradation.

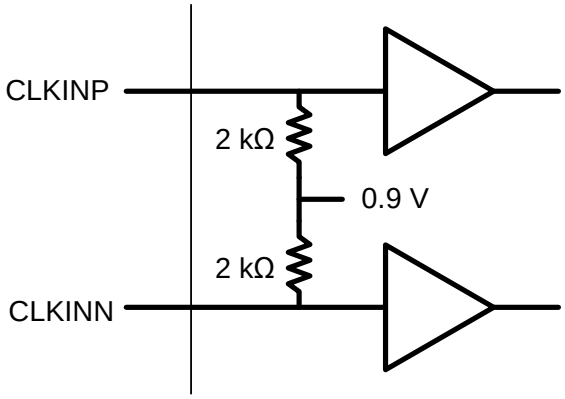

图 68. Equivalent Clock Input Circuit

7.3.9 Input Clock Divider

The ADS54J54 is equipped with two internal dividers on the clock input – one on channel AB and one on channel CD. The clock divider allows operation with a faster input clock simplifying the system clock distribution design. The clock dividers can be bypassed (/1) for operation with a 500-MHz clock while /2 option supports a maximum input clock of 1 GHz and the /4 option a maximum input clock frequency of 2 GHz. Different divider options can be selected for channel AB and channel CD clock output. By default the divider output of channel AB block is routed to all 4 channels but the configuration can be customized with different SPI register settings to use either the channel AB or CD divider blocks for any two channels.

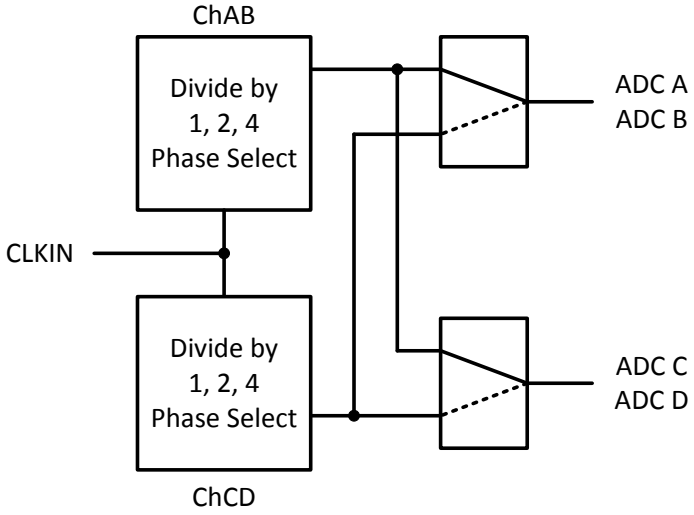

图 69. Input Clock Divider

7.3.10 Power-Down Control

The power down functions of the ADS54J54 can be controlled either through the parallel control pin (ENABLE) or through a SPI register setting. Power-down modes for the different channels as well as for the JESD204B interface are supported.

The ADS54J54 supports the following power-down modes. The analog sleep mode configurations are in register 0x05/06 and the JESD204b sleep mode configurations are in register 0x1E and 0x1F.

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表 4. Low-Power Mode Power Consumption and Wake-Up Times

Configuration	Power Consumption	Wake-Up Time
Global power down	24 mW	Needs JESD resynch
Standby	31 mW	Needs JESD resynch
Deep sleep	791 mW	1.4 ms
Light sleep	1.68 W	8 µs

Control power-down function through ENABLE pin:

1. Configure power-down mode in register 0x05 and 0x1E
2. Normal operation: ENABLE pin high
3. Power-down mode: ENABLE pin low

Control power-down function through SPI (ENABLE pin always high):

1. Assign power-down mode in register 0x06 and 0x1F
2. Normal operation: 0x06 and 0x1F are 0xFFFF
3. Power-down mode: configure power down mode in register 0x06 and 0x1F

7.3.11 Device Configuration

The serial interface (SIF) included in the ADS54J54 is a simple 3- or 4-pin interface. In normal mode, 3 pins are used to communicate with the device. There is an enable (SDENb), a clock (SCLK), and a bidirectional IO port (SDATA). If the user would like to use the 4-pin interface, one write must be implemented in the 3-pin mode to enable 4-pin communications. In this mode, the SDOUT pin becomes the dedicated output. The serial interface has an 8-bit address word and a 16-bit data word. The first rising edge of SCLK after SDENb goes low will latch the read or write bit. If a high is registered, then a read is requested, if it is low, then a write is requested. SDENb must be brought high again before another transfer can be requested.

7.3.12 JESD204B Interface Initialization Sequence

After power-up, the internal JESD204B digital block must be initialized with the following sequence of steps:

1. Set JESD RESET AB/CD and JESD INIT AB/CD to 0 (address 0x0D, value 0x0000)
2. Set JESD INIT AB/CD to 1 (0x0D, 0x0202)
3. Set JESD RESET AB/CD to 1 (0x0D, 0x0303)
4. Configure all other JESD register and clock settings. If those settings change later on, this initialization sequence must be repeated.
5. Set JESD RESET AB/CD to 0 (0x0D, 0x0202)
6. Set JESD RESET AB/CD to 1 (0x0D, 0x0303)
7. Wait for two SYSREF pulses
8. Set JESD INIT AB/CD to 0 (0x0D, 0x0101)

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7.3.13 Device and Register Initialization

After power-up, the internal registers must be initialized to their default values through a hardware reset by applying a low pulse on the SRESETb pin (of width greater than 10 ns), as shown in 图 1. If required later during operation, the serial interface registers can be cleared by applying:

- Another hardware reset using the SRESETb pin
- A software reset (bit D0 in register 0x00). This setting resets the internal registers to the default values and then self-resets the RESET bit (D0) back to 0. In this case, the RESET pin is kept high.
- Write the data in 表 5 to the following registers after every device power-up or reset for optimum AC performance:

表 5. AC Performance

ADDRESS	DATA	REASON
0x06	0xFFDF	turn off fuse logic for power savings - not required
0x44	0x0074	trim value - required
0x47	0x0074	trim value - required
0x4C	0x4000	trim value - required
0x50	0x0800	trim value - required
0x51	0x0074	trim value - required
0x54	0x0074	trim value - required
0x59	0x4000	trim value - required
0x5D	0x0800	trim value - required

7.4 Device Functional Modes

7.4.1 Operating Modes

表 6 details the five different operating modes. A pair of channels (channel A and B and channel C and D) can be configured in the same operating mode.

表 6. Operating Modes Information

Channel Sampling Rate (MSPS)	Digital Feature	Output Data Rate (MSPS)	Output Resolution	Output SerDes Rate (GSPS)	Number of Lanes per Channel
500	Decimation by 2	250	14 bit	5.0	1
500	Bypass digital logic mode	500	14 bit	5.0	2

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7.4.2 Output Format

表 7 provides detailed information on how the MSB or LSB get aligned for the different output data rates and resolution in the different operating modes.

表 7. Output Data Formats

Output Rate	Mode	Resolution	Bit 15	Bit 14	Bit 13	Bit 12	Bit 11	Bit 10	Bit 9	Bit 8	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
250 MSPS	Decimate by 2	14 bit	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	OVR	0
500 MSPS	Bypass digital logic mode	14 bit	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	OVR	0

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7.5 Programming

7.5.1 Serial Register Write

The internal register of the ADS54J54 can be programmed following these steps:

1. Drive SDENb pin low.
2. Set the R/W bit to '0' (bit A7 of the 8 bit address).
3. Initiate a serial interface cycle specifying the address of the register (A6 to A0) whose content has to be written.
4. Write 16-bit data which is latched on the rising edge of SCLK.

表 8. Serial Register Read or Write Timing(1)

PARAMETER		MIN	TYP	MAX	UNIT
f_{SCLK}	SCLK frequency (equal to 1 / t_{SCLK})	>DC		10	MHz
t_{SLOADS}	SDENb to SCLK setup time	50			ns
t_{SLOADH}	SCLK to SDENb hold time	50			ns
t_{DSU}	SDATA setup time	50			ns
t_{DH}	SDATA hold time	50			ns

(1) Typical values at 25°C; minimum and maximum values across the full temperature range: T_{MIN} = –40°C to T_{MAX} = 85°C, AVDD33 = 3.3 V; AVDD18 = 1.9 V; AVDDC, DVDD, IOVDD, PLLVDD = 1.8 V, unless otherwise noted.

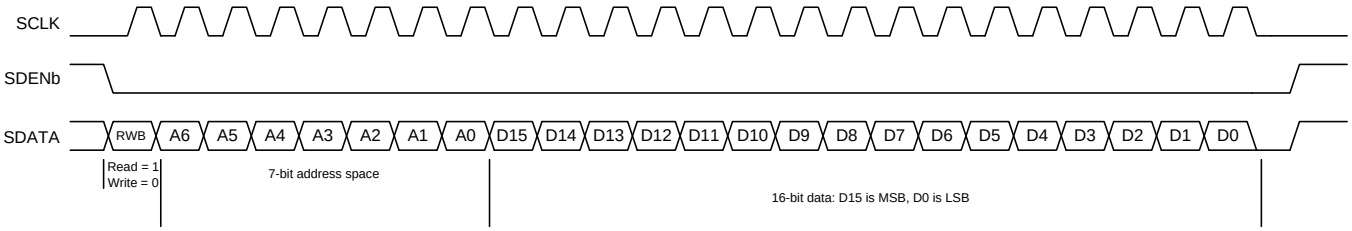

图 70. Serial Register Write Timing Diagram

7.5.2 Serial Register Readout

The device includes a mode where the contents of the internal registers can be read back using the SDOUT and SDATA pins. This read-back mode may be useful as a diagnostic check to verify the serial interface communication between the external controller and the channel.

1. Drive SDENb pin low.
2. Set the RW bit (A7) to 1. This setting disables any further writes to the registers.
3. Initiate a serial interface cycle specifying the address of the register (A6 to A0) whose content has to be read.
4. The device outputs the contents (D15 to D0) of the selected register on the SDOUT/SDATA pin.
5. The external controller can latch the contents at the SCLK rising edge.
6. To enable register writes, reset the RW register bit to 0.

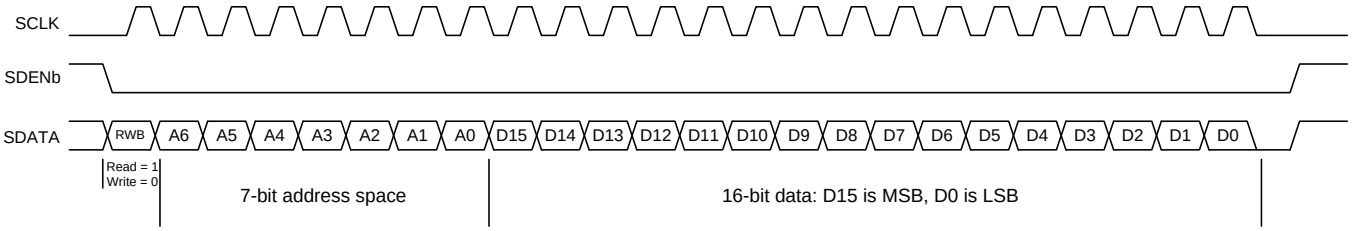

图 71. Serial Register Read Timing Diagram

7.6 Register Maps

Register Address	Register Data															
A7 to A0 in hex	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	3/4 WIRE	FORMAT	DEC EN AB	HP/LP AB	0	DEC EN CD	HP/LP CD	0	0	0	0	0	0	0	0	RESET
1	MODE 1	0	1	0	FOVR THRESH AB			FOVR LENGTH AB		FOVR THRESH CD			FOVR LENGTH CD		1	0
2	0	1	0		0	0	0	0	0	0	0	0	0	0	0	0
3	0	CLK SEL CD	CLK DIV CD		0	CLK PHASE SELECT CD			SYSREF SEL CD	CLK SEL AB	CLK DIV AB		0	CLK PHASE SELECT AB		
4	OVRA OUT EN	OVRB OUT EN	OVRC OUT EN	OVRD OUT EN	SYSREF AB DELAY		SYSREF CD DELAY		0	0	0	0	SYNCb AB EN	SYNCb CD EN	1	1
5	ANALOG SLEEP MODES – ENABLE PIN															
6	ANALOG SLEEP MODES – SPI															SYSREFCD EN
7	0	0	0	0	0	0	CLK SW AB	1	0	1	0	0	0	1	0	0
8	0	0	0	0	0	0	CLK SW CD	1	0	1	0	0	0	1	0	0
C	0	0	1	1	0	0	0	1	1	1	SYSREF JESD MODE CD			SYSREF JESD MODE AB		
D	0	0	0	0	0	0	JESD INIT CD	JESD RESET CD	0	0	0	0	0	0	JESD INIT AB	JESD RESET AB
E	0	0	0	0	0	0	0	0	TX LANE EN CD				TX LANE EN AB			
F	0	0	0	0	0	0	CTRL F AB		0	0	0	0	0	0	CTRL M AB	
10	0	0	0	0	0	0	CTRL K AB					0	0	0	CTRL L AB	
13	0	0	0	0	0	0	0	0	0	INV SYNCb AB	HD AB	SCR EN AB	0	0	0	0
16	0	0	0	0	0	0	CTRL F CD		0	0	0	0	0	0	CTRL M CD	
17	0	0	0	0	0	0	CTRL K CD					0	0	0	CTRL L CD	
1A	0	0	0	0	0	0	0	0	0	INV SYNCb CD	HD CD	SCR EN CD	0	0	0	0
1D	0	0	0	0	0	0	0	0	0	TEST PATTERN EN CD	TEST PATTERN EN AB	0	TEST PATTERN	0	0	0
1E	0	0	0	0	0	0	JESD SLEEP MODES – ENABLE PIN									
1F	1	1	1	1	1	1	JESD SLEEP MODES – SPI									
20	JESD LANE POLARITY INVERT								PRBS EN							
21	0	PRBS SEL		0	0	0	0	0	0	0	0	0	0	VREF SEL		
63	0	0		0	0	0	0	0	TEMP SENSOR							
64	PRE EMP SEL AB				PRE EMP EN AB				DCC EN AB				0	0	0	0
67	OUTPUT CURRENT CONTROL AB															
68	PRE EMP SEL CD				PRE EMP EN CD				DCC EN CD				0	0	0	0
6B	OUTPUT CURRENT CONTROL CD															
6C	0	0	0	0	0	0	0	0	0	0	0	0	0	0	JESD PLL CD	JESD PLL AB

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7.6.1 Register Descriptions

7.6.1.1 Register Address 0

图 72. Register Address 0, Reset 0x0000, Hex = 0

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
3/4 WIRE	FORMAT	DEC EN AB	HP/LP AB	0	DEC EN CD	HP/LP CD	0	0	0	0	0	0	0	0	RESET

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 9. Register Address 0 Field Descriptions

Bit	Field	Type	Reset	Description
D15	3/4 WIRE	R/W	0	Enables 4-bit serial interface when set 0 = 3-wire SPI (SDATA is bidirectional) 1 = 4-wire SPI (SDOUT is data output)
D14	FORMAT	R/W	0	Selects digital output format 0 = Output is 2s complement 1 = Offset binary
D13	DEC EN AB	R/W	0	Enables decimation filter for channel AB 0 = Normal operation 1 = Decimation filter enabled
D12	HP/LP AB	R/W	0	Determines high-pass or low-pass configuration of decimation filter for channel AB 0 = Low pass 1 = High pass
D10	DEC EN CD	R/W	0	Enables decimation filter for channel CD 0 = Normal operation 1 = Decimation filter enabled
D9	HP/LP CD	R/W	0	Determines high-pass or low-pass configuration of decimation filter for channel CD 0 = Low pass 1 = High pass
D0	RESET	R/W	0	Software reset, self clears to 0 0 = Normal operation 1 = Execute software reset

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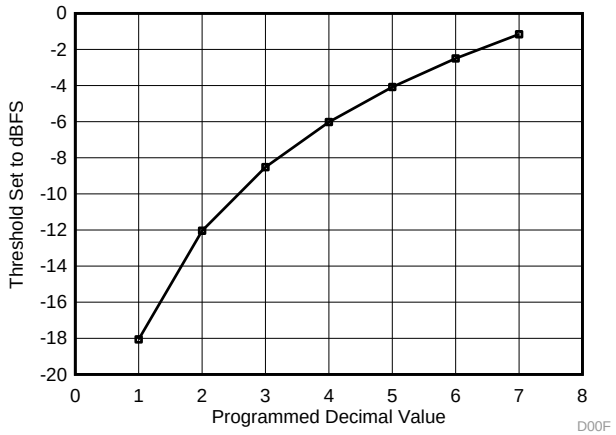
7.6.1.2 Register Address 1

图 73. Register Address 1, Reset 0xAF7A, Hex = 1

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
MODE 1	0	1	0	FOVR THRESH AB			FOVR LENGTH AB		FOVR THRESH CD			FOVR LENGTH CD		1	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 10. Register Address 1 Field Descriptions

Bit	Field	Type	Reset	Description
D15	MODE 1	R/W	1	Set bit D15 to 0 for optimum performance
D13		R	1	Reads back 1
D11:D9	FOVR THRESH AB	R/W	111	Sets fast OVR thresholds for channel A and B The fast over-range detection is triggered 6 output clock cycles after the overload condition occurs. The threshold at which the OVR is triggered is: Input full scale × [decimal value of <over-range threshold>] / 8. After power-up or reset, the default value is 7 (decimal), which corresponds to an OVR threshold of 1.16-dB below full scale (20 × log(7/8)).  **图 74. OVR Detection Threshold**
D8:D7	FOVR LENGTH AB	R/W	10	Determines minimum pulse length for FOVR output 00 = 1 clock cycle 01 = 2 clock cycles 10 = 4 clock cycles 11 = 8 clock cycles
D6:D4	FOVR THRESH CD	R/W	111	Sets fast OVR thresholds for channel C and D See description for channel A and B
D3:D2	FOVR LENGTH CD	R/W	10	Determines minimum pulse length for FOVR output 00 = 1 clock cycle 01 = 2 clock cycles 10 = 4 clock cycles 11 = 8 clock cycles
D1		R	1	Reads back 1

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7.6.1.3 Register Address 3

图 75. Register Address 3, Reset: 0x4040, Hex = 3

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	CLK SEL CD	CLK DIV CD		0	CLK PHASE SELECT CD			SYSREF SEL CD	CLK SEL AB	CLK DIV AB		0	CLK PHASE SELECT AB		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 11. Register Address 3 Field Descriptions

Bit	Field	Type	Reset	Description
D14	CLK SEL CD	R/W	1	Clock source selection for channel C and D 0 = Channel CD clock output divider 1 = Channel AB clock output divider (default)
D13:D12	CLK DIV CD	R/W	00	Channel CD clock divider setting 00 = Clock input is up to 500 MHz. Input clock is not divided (default) 01 = /2 10 = /4 11 = Not used
D10:D8	CLK PHASE SELECT CD	R/W	000	Selects phase of channel divided clock, but depends on clock divider setting. When clock CD divider is set to: /1 = 2 phases are available (0º or 180º) /2 = 4 phases are available (0º, 90º, 180º or 270º) /4 = 8 phases are available (0º, 45º, 90º, 135º, 180º, 225º, 270º or 315º) When switching clock phases, register 0x08, D9 must be enabled first and then disabled after the switch to ensure glitch-free operation.
D7	SYSREF SEL CD	R/W	0	SYSREF Input selection for channel C and D 0 = Use SYSREFAB inputs (default) 1 = Use SYSREFCD inputs
D6	CLK SEL AB	R/W	1	Clock source selection for channel A and B 0 = Channel CD clock output divider 1 = Channel AB clock output divider (default)
D5:D4	CLK DIV AB	R/W	00	Channel AB clock divider setting 00 = Clock input is up to 500 MHz. Input clock is not divided (default) 01 = /2 10 = /4 11 = Not used
D2:D0	CLK PHASE SELECT AB	R/W	000	Selects phase of channel AB divided clock, but depends on clock divider setting. When clock divider is set to: /1 = 2 phases are available (0º or 180º) /2 = 4 phases are available (0º, 90º, 180º or 270º) /4 = 8 phases are available (0º, 45º, 90º, 135º, 180º, 225º, 270º or 315º) When switching clock phases, register 0x07, D9 must be enabled first and then disabled after the switch to ensure glitch-free operation.

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7.6.1.4 Register Address 4

图 76. Register Address 4, Reset: 0x000F, Hex = 4

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
OVRA OUT EN	OVRB OUT EN	OVRC OUT EN	OVRD OUT EN	SYSREF AB DELAY		SYSREF CD DELAY		0	0	0	0	SYNCb AB EN	SYNCb CD EN	1	1

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 12. Register Address 4 Field Descriptions

Bit	Field	Type	Reset	Description
D15	OVRA OUT EN	R/W	0	OVRA pin output enable 0 = Not used (default) 1 = OVRA is an output
D14	OVRB OUT EN	R/W	0	OVRB pin output enable 0 = Not used (default) 1 = OVRB is an output
D13	OVRC OUT EN	R/W	0	OVRC pin output enable 0 = Not used (default) 1 = OVRC is an output
D12	OVRD OUT EN	R/W	0	OVRD pin output enable 0 = Not used (default) 1 = OVRD is an output
D11:D10	SYSREF AB DELAY	R/W	00	Programmable input delay on SYSREFAB input 00 = 0-ps delay (default) 01 = 200-ps delay 10 = 100-ps delay 11 = 300-ps delay
D9:D8	SYSREF CD DELAY	R/W	00	Programmable input delay on SYSREFCD input 00 = 0-ps delay (default) 01 = 200-ps delay 10 = 100-ps delay 11 = 300-ps delay
D3	SYNCb AB EN	R/W	1	SYNCbAB input buffer enable 0 = Input buffer disabled 1 = Input buffer enabled (default)
D2	SYNCb CD EN	R/W	1	SYNCbCD input buffer enable 0 = Input buffer disabled 1 = Input buffer enabled (default)
D1		R	1	Reads back 1
D0		R	1	Reads back 1

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7.6.1.5 Register Address 5

图 77. Register Address 5, Reset: 0x0000, Hex = 5

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
ANALOG SLEEP MODES – ENABLE pin															

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 13. Register Address 5 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D0	ANALOG SLEEP MODES – ENABLE pin	R/W		Power-down function assigned to ENABLE pin. When any bit is set, the corresponding function is always enabled regardless of status of the ENABLE pin. This assumes address 0x06 is in default configuration.
D13		R/W	0	Light sleep channel A
D11		R/W	0	Light sleep channel B
D9		R/W	0	Light sleep channel C
D7		R/W	0	Light sleep channel D
D6		R/W	0	Temperature sensor
D4		R/W	0	Clock buffer
D3		R/W	0	Clock divider channel AB
D2		R/W	0	Clock divider channel CD
D1		R/W	0	Buffer SYSREFAB
D0		R/W	0	Buffer SYSREFCD

表 14. Configurations When ENABLE Pin is Low

	Description
0000 0000 0000 0000	Global power down
1000 0000 0000 0000	Standby
1000 0000 0001 1111	Deep sleep
1010 1010 1001 1111	Light sleep (if unused, clock divider CD and SYSREFCD can be set to 0 also)

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7.6.1.6 Register Address 6

图 78. Register Address 6, Reset: 0xFFFF, Hex = 6

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
ANALOG SLEEP MODES – SPI															1

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 15. Register Address 6 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D1	ANALOG SLEEP MODES – SPI			Power-down function controlled via SPI. When a bit is set to 0, the function is powered down when ENABLE pin is high. However, register 0x05 has higher priority. For example, if D13 (deep sleep channel A) in 0x05 is enabled, it cannot be powered down with the SPI.
D13		R/W	1	Light sleep channel A
D11		R/W	1	Light sleep channel B
D9		R/W	1	Light sleep channel C
D7		R/W	1	Light sleep channel D
D6		R/W	1	Temperature sensor
D4		R/W	1	Clock buffer
D3		R/W	1	Clock divider channel AB
D2		R/W	1	Clock divider channel CD
D1		R/W	1	Buffer SYSREFAB
D0		R/W	1	Should be left set to 1

表 16. Configurations When ENABLE Pin is High

	Description
0000 0000 0000 000	Global power down
1000 0000 0000 000	Standby
1000 0000 0001 111	Deep sleep
1010 1010 1001 111	Light sleep
1111 1111 1111 111	Normal operation

Control power down function through ENABLE pin:

1. Configure power-down mode in register 0x05
2. Normal operation: ENABLE pin high
3. Power-down mode: ENABLE pin low

Control power down function through SPI (ENABLE pin always high):

1. Assign power-down mode in register 0x06
2. Normal operation 0x06 is 0xFFFF
3. Power-down mode: configure power down mode in register 0x06

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7.6.1.7 Register Address 7

图 79. Register Address 7, Reset: 0x0144, Hex = 7

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	CLK SW AB	1	0	1	0	0	0	1	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 17. Register Address 7 Field Descriptions

Bit	Field	Type	Reset	Description
D9	CLK SW AB	R/W	0	User should set this bit to 1 when changing the clock phase of the clock divider AB. After the change is complete user needs to write this bit back to 0.
D8		R	1	Reads back 1
D6		R	1	Reads back 1
D2		R	1	Reads back 1

7.6.1.8 Register Address 8

图 80. Register Address 8, Reset: 0x0144, Hex = 8

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	CLK SW CD	1	0	1	0	0	0	1	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 18. Register Address 8 Field Descriptions

Bit	Field	Type	Reset	Description
D9	CLK SW CD	R/W	0	User should set this bit to 1 when changing the clock phase of the clock divider CD. After the change is complete user needs to write this bit back to 0.
D8		R	1	Reads back 1
D6		R	1	Reads back 1
D2		R	1	Reads back 1

7.6.1.9 Register Address 12

图 81. Register Address 12, Reset: 0x31E4, Hex = C

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	1	1	0	0	0	1	1	1	SYSREF JESD MODE CD			SYSREF JESD MODE AB		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 19. Register Address 12 Field Descriptions

Bit	Field	Type	Reset	Description
D13		R	1	Reads back 1
D12		R	1	Reads back 1
D8		R	1	Reads back 1
D7		R	1	Reads back 1
D6		R	1	Reads back 1

表 19. Register Address 12 Field Descriptions (接下页)

Bit	Field	Type	Reset	Description
D5:D3	SYSREF JESD MODE CD	R/W	100	Determines how SYSREF is used in the JESD block for channel CD 000 = Ignore SYSREF input 001 = Use all SYSREF pulses 010 = Use only the next SYSREF pulse 011 = Skip one SYSREF pulse then use only the next one 100 = Skip one SYSREF pulse then use all pulses (default) 101 = Skip two SYSREF pulses and then use one 111 = Skip two SYSREF pulses and then use all
D2:D0	SYSREF JESD MODE AB	R/W	100	Determines how SYSREF is used in the JESD block for channel AB. Same functionality as SYSREF JESD MODE CD

7.6.1.10 Register Address 13

图 82. Register Address 13, Reset: 0x0202, Hex = D

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	JESD INIT CD	JESD RESET CD	0	0	0	0	0	0	JESD INIT AB	JESD RESET AB

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 20. Register Address 13 Field Descriptions

Bit	Field	Type	Reset	Description
D9	JESD INIT CD	R/W	1	Puts the JESD block in INITIALIZATION state when set high. In this state the JESD parameters can be programmed and the outputs will stay at 0. See also JESD start-up sequence.
D8	JESD RESET CD	R/W	0	Resets the JESD block when low
D1	JESD INIT AB	R/W	1	Puts the JESD block in initialization state when set high. In this state the JESD parameters can be programmed and the outputs will stay at 0.
D0	JESD RESET AB	R/W	0	Resets the JESD block when low

7.6.1.11 Register Address 14

图 83. Register Address 14, Reset: 0x00FF, Hex = E

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	0	0	TX LANE EN CD				TX LANE EN AB			

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 21. Register Address 14 Field Descriptions

Bit	Field	Type	Reset	Description
D7:D4	TX LANE EN CD	R/W	1111	Enables JESD204B transmitter for channel C and D. Set to 1 to enable. D7 = Lane DD1 D6 = Lane DD0 D5 = Lane DC1 D4 = Lane DC0
D3:D0	TX LANE EN AB	R/W	1111	Enables JESD204B transmitter for channel A and B. Set to 1 to enable. D3 = Lane DB1 D2 = Lane DB0 D1 = Lane DA1 D0 = Lane DA0

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7.6.1.12 Register Address 15

图 84. Register Address 15, Reset: 0x0001, Hex = F

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	CTRL F AB		0	0	0	0	0	0	CTRL M AB	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 22. Register Address 15 Field Descriptions

Bit	Field	Type	Reset	Description
D9:D8	CTRL F AB	R/W	00	Controls number of octets per frame for channel AB. 00 = F = 1 (default) 01 = F = 2
D1:D0	CTRL M AB	R/W	01	Controls number of converters per link for channel AB. 01 = M = 2. This is the only valid option (default)

7.6.1.13 Register Address 16

图 85. Register Address 16, Reset: 0x03E3, Hex = 10

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	CTRL K AB					0	0	0	CTRL L AB	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 23. Register Address 16 Field Descriptions

Bit	Field	Type	Reset	Description
D9:D5	CTRL K AB	R/W	11111	Controls number of frames per multi-frame for channel AB. 0: K = 1 30 K = 31 1: K = 2 31 K = 32 (default) And so forth
D1:D0	CTRL L AB	R/W	11	Controls number of lanes for channel AB. 01: L = 2 11: L = 4 (default)

7.6.1.14 Register Address 19

图 86. Register Address 19, Reset: 0x0020, Hex = 13

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	0	0	0	INV SYNCb AB	HD AB	SCR EN AB	0	0	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 24. Register Address 19 Field Descriptions

Bit	Field	Type	Reset	Description
D6	INV SYNCb AB	R/W	0	Inverts polarity of SYNCbAB input 0 = Normal operation 1 = Polarity inverted
D5	HD AB	R/W	1	Enables high density mode for channel AB. This mode is needed for LMFS = 4221. 0 = High-density mode disabled for mode LMFS = 2221 1 = High-density mode enabled for mode LMFS = 4221 (default)
D4	SCR EN AB	R/W	0	Enables scramble mode for channel AB 0 = Scramble mode disabled (default) 1 = Scramble mode enabled

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7.6.1.15 Register Address 22

图 87. Register Address 22, Reset: 0x0001, Hex = 16

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	CTRL F CD		0	0	0	0	0	0	CTRL M CD	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 25. Register Address 22 Field Descriptions

Bit	Field	Type	Reset	Description
D9:D8	CTRL F CD	R/W	00	Controls number of octets per frame for channel CD. 00: F = 1 (default) 01: F = 2
D1:D0	CTRL M CD	R/W	01	Controls number of converters per link for channel CD. 01: M = 2. This is the only valid option (default)

7.6.1.16 Register Address 23

图 88. Register Address 23, Reset: 0x03E3, Hex = 17

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	CTRL K CD					0	0	0	CTRL L CD	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 26. Register Address 23 Field Descriptions

Bit	Field	Type	Reset	Description
D9:D5	CTRL K CD	R/W	11111	Controls number of frames per multi-frame for channel CD 0: K = 1 30 K = 31 1: K = 2 31 K = 32 (default) And so forth
D1:D0	CTRL L CD	R/W	11	Controls number of lanes for channel CD 01: L = 2 11: L = 4 (default)

7.6.1.17 Register Address 26

图 89. Register Address 26, Reset: 0x0020, Hex = 1A

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	0	0	0	INV SYNCb CD	HD CD	SCR EN CD	0	0	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 27. Register Address 26 Field Descriptions

Bit	Field	Type	Reset	Description
D6	INV SYNCb CD	R/W	0	Inverts polarity of SYNCbCD input 0 = Normal operation 1 = Polarity inverted
D5	HD CD	R/W	1	Enables high density mode for channel CD. This mode is needed for LMFS = 4221. 0 = High density mode disabled for mode LMFS = 2221 1 = High density mode enabled for mode LMFS = 4221 (default)
D4	SCR EN CD	R/W	0	Enables scramble mode for channel CD 0 = Scramble mode disabled (default) 1 = Scramble mode enabled

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7.6.1.18 Register Address 29

图 90. Register Address 29, Reset: 0x0000, Hex = 1D

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	0	0	0	TEST PATTERN EN CD	TEST PATTERN EN AB	0	TEST PATTERN	0	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 28. Register Address 29 Field Descriptions

Bit	Field	Type	Reset	Description
D6	TEST PATTERN EN CD	R/W	0	Enables test pattern output for channel C and D 0 = Normal operation 1 = Test pattern output enabled
D5	TEST PATTERN EN AB	R/W	0	Enables test pattern output for channel A and B 0 = Normal operation 1 = Test pattern output enabled
D4	TEST PATTERN	R/W	0	Selects test pattern 0 = RAMP pattern 1 = Output alternates between 0x1555 and 0x2AAA

7.6.1.19 Register Address 30

图 91. Register Address 30, Reset: 0x0000, Hex = 1E

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	JESD SLEEP MODES – ENABLE pin									

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 29. Register Address 30 Field Descriptions

Bit	Field	Type	Reset	Description
D9:D0	JESD SLEEP MODES – ENABLE pin	R/W	0 0000 0000	Power-down function assigned to ENABLE pin. When any bit is set, the corresponding function is always enabled regardless of status of the ENABLE pin. D9 = JESD PLL channel CD D8 = JESD PLL channel AB D7 = Lane DD1 D6 = Lane DD0 D5 = Lane DC1 D4 = Lane DC0 D3 = Lane DB1 D2 = Lane DB0 D1 = Lane DA1 D0 = Lane DA0

表 30. Configurations

	Description
00 0000 0000	Global power down (default)
00 0000 0000	Standby
11 0000 0000	Deep sleep
11 0000 0000	Light sleep

7.6.1.20 Register Address 31

图 92. Register Address 31, Reset: 0xFFFF, Hex = 1F

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
1	1	1	1	1	1	JESD SLEEP MODES – SPI									

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 31. Register Address 31 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D0	JESD SLEEP MODES – SPI	R/W	11 1111 1111	Power-down function controlled via SPI. When a bit is set to 0, the function is powered down when ENABLE pin is high. However register 0x1E has higher priority. For example, if D9 (JESD PLL channel CD) in 0x1E is enabled, it cannot be powered down with the ENABLE pin. D9 = JESD PLL channel CD D8 = JESD PLL channel AB D7 = Lane DD1 D6 = Lane DD0 D5 = Lane DC1 D4 = Lane DC0 D3 = Lane DB1 D2 = Lane DB0 D1 = Lane DA1 D0 = Lane DA0

表 32. Configurations

	Description
00 0000 0000	Global power down
00 0000 0000	Standby
11 0000 0000	Deep sleep
11 0000 0000	Light sleep
11 1111 1111	Normal operation (default)

Control power down function through ENABLE pin:

1. Configure power down mode in register 0x1E
2. Normal operation: ENABLE pin high
3. Power down mode: ENABLE pin low

Control power down function through SPI (ENABLE pin always high):

1. Assign power down mode in register 0x1F
2. Normal operation 0x1F is 0xFFFF
3. Power-down mode: configure power down mode in register 0x1F

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7.6.1.21 Register Address 32

图 93. Register Address 32, Reset: 0x0000, Hex = 20

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
JESD LANE POLARITY INVERT								PRBS EN							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 33. Register Address 32 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D8	JESD LANE POLARITY INVERT	R/W	0000 0000	Set to 1 for polarity inversion D15 = Lane DD1 D14 = Lane DD0 D13 = Lane DC1 D12 = Lane DC0 D11 = Lane DB1 D10 = Lane DB0 D9 = Lane DA1 D8 = Lane DA0
D7:D0	PRBS EN	R/W	0000 0000	Outputs PRBS pattern selected in address 0x21 on the selected serial output lanes D7 = Lane DD1 D6 = Lane DD0 D5 = Lane DC1 D4 = Lane DC0 D3 = Lane DB1 D2 = Lane DB0 D1 = Lane DA1 D0 = Lane DA0

7.6.1.22 Register Address 33

图 94. Register Address 33, Reset: 0x0000, Hex = 21

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
	PRBS SEL		0	0	0	0	0	0	0	0	0	0	VREF SEL		

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 34. Register Address 33 Field Descriptions

Bit	Field	Type	Reset	Description
D14:D13	PRBS SEL	R/W	00	Selects different PRBS output pattern (these are not 8b/10b encoded) 000 = $2^{31} – 1$ 001 = $2^{7} – 1$ 010 = $2^{15} – 1$ 011 = $2^{23} – 1$
D2:D0	VREF SEL	R/W	000	Selects different input full-scale amplitude by adjusting voltage reference setting 000 = Full scale is 1.25 Vpp (default) 001 = Full scale is 1.35 Vpp 010 = Full scale is 1.5 Vpp 011 = External 100 = Full scale is 1.15 Vpp 101 = Full scale is 1.0 Vpp

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7.6.1.23 Register Address 99

图 95. Register Address 99,Reset: 0x0000, Hex = 63

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	0	TEMP SENSOR								

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 35. Register Address 99 Field Descriptions

Bit	Field	Type	Reset	Description
D8:D0	TEMP SENSOR	R	undefined	Value of on chip temperature sensor (read only). Value is 2s complement of die temperature sensor in °C For example: 0x0032 equals 50°C

7.6.1.24 Register Address 100

图 96. Register Address 100, Reset: 0x0000, Hex = 64

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
PRE EMP SEL AB				PRE EMP EN AB				DCC EN AB				0	0	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 36. Register Address 100 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D12	PRE EMP SEL AB	R/W	0000	Selects pre-emphasis of serializers for channel A and B 0 = Pre-emphasis 1 = De-emphasis
D11:D8	PRE EMP EN AB	R/W	0000	Enables pre-emphasis, 0 = disabled, 1 = enabled D11 = Lane DB1 D10 = Lane DB0 D9 = Lane DA1 D8 = Lane DA0
D7:D4	DCC EN AB	R/W	0000	Enables the duty cycle correction circuit for each of the serializers D7 = Lane DB1 D6 = Lane DB0 D5 = Lane DA1 D4 = Lane DA0

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7.6.1.25 Register Address 103

图 97. Register Address 103, Reset: 0x0000, Hex = 67

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
OUTPUT CURRENT CONTROL AB															

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 37. Register Address 103 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D0	OUTPUT CURRENT CONTROL AB	R/W	0000 0000 0000 0000	Selects pre-emphasis current for the serializers. There are 4 bit per serializer of channel A and B. D15:D12 = Lane DB1 D11:D8 = Lane DB0 D7:D4 = Lane DA1 D3:D0 = Lane DA0

表 38. Pre-Emphasis Level is: Decimal Value / 30

	Description
0000	Normal operation
0001	1 / 30
0010	2 / 30
and so forth	

7.6.1.26 Register Address 104

图 98. Register Address 104, Reset: 0x0000, Hex = 68

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
PRE EMP SEL CD				PRE EMP EN CD				DCC EN CD				0	0	0	0

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 39. Register Address 104 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D12	PRE EMP SEL CD		0000	Selects pre-emphasis of serializers for channel C and D 0 = Pre-emphasis 1 = De-emphasis
D11:D8	PRE EMP EN CD		0000	Enables pre-emphasis, 0 = disabled, 1 = enabled D11 = Lane DD1 D10 = Lane DD0 D9 = Land DC1 D8 = Lane DC0
D7:D4	DCC EN CD		0000	Enables the duty cycle correction circuit for each of the serializers D7 = Lane DD1 D6 = Lane DD0 D5 = Land DC1 D4 = Lane DC0

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7.6.1.27 Register Address 107

图 99. Register Address 107, Reset: 0x0000, Hex = 6B

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
OUTPUT CURRENT CONTROL CD															

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 40. Register Address 107 Field Descriptions

Bit	Field	Type	Reset	Description
D15:D0	OUTPUT CURRENT CONTROL CD	R/W	0000 0000 0000 0000	Selects pre-emphasis current for the serializers. There are 4 bit per serializer of channel C and D. D15:D12 = Lane DD1 D11:D8 = Lane DD0 D7:D4 = Land DC1 D3:D0 = Lane DC0

表 41. Pre-Emphasis Level is: Decimal Value / 30

	Description
0000	Normal operation
0001	1 / 30
0010	2 / 30
And so forth	

7.6.1.28 Register Address 108

图 100. Register Address 108, Hex = 3C

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	0	0	0	0	0	0	0	0	0	0	0	0	JESD PLL CD	JESD PLL AB

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

表 42. Register Address 108 Field Descriptions(1)

Bit	Field	Type	Reset	Description
D1	JESD PLL CD	R	1	JESD PLL for channel CD lost lock when flag is set high
D0	JESD PLL CD	R	1	JESD PLL for channel AB lost lock when flag is set high

(1) Register values in address 0x6C are read only alarms

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8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

In the design of any application involving a high-speed data converter, particular attention should be paid the design of the analog input, the clocking solution, and careful layout of the clock and analog signals. In addition, the JESD204B interface means there now are high-speed serial lines that should be handled to preserve adequate signal integrity at the device that receives the sample data. The ADS54J54 evaluation module (EVM) is one practical example of the design of the analog input circuit and clocking solution, as well as a practical example of good circuit board layout practices around the ADC.

8.2 Typical Application

The analog inputs of the ADS54J54 must be fully differential and biased to a desired common mode voltage, VCM. Therefore, there will be a signal conditioning circuit for each of the analog inputs. If the amplitude of the input circuit is such that no gain is needed to make full use of the full-scale range of the ADC, then a transformer coupled circuit as in 图 101 may be used with good results. The transformer coupling is inherently low-noise, and inherently AC-coupled so that the signal may be biased to VCM after the transformer coupling. If signal gain is required, or the input bandwidth is to include the spectrum all the way down to DC such that AC coupling is not possible, then an amplifier-based signal conditioning circuit would be required.

By using the simple drive circuit of 图 101, uniform performance can be obtained over a wide frequency range. The buffers present at the analog inputs of the device help isolate the external drive source from the switching currents of the sampling circuit.

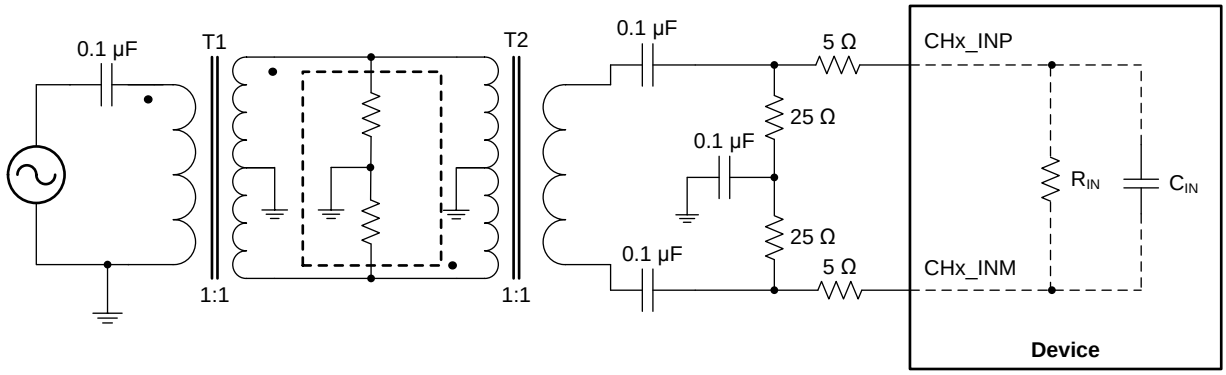

图 101. Input Drive Circuit

Typical Application (接下页)

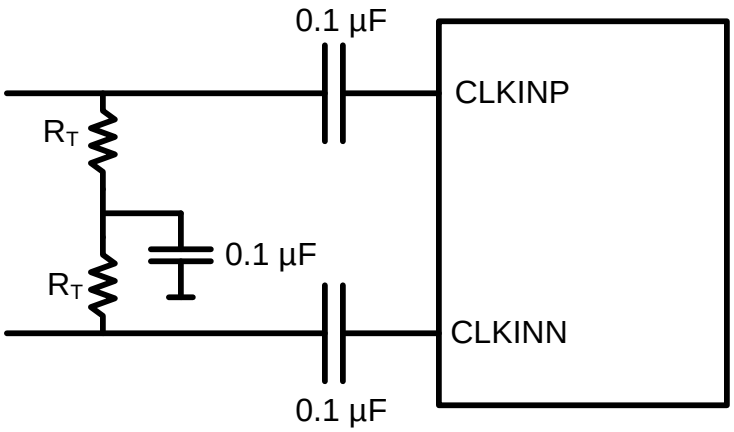

图 102. Recommended Differential Clock Driving Circuit

8.3 Design Requirements

The ADS54J54 requires a fully differential analog input with a full-scale range not to exceed 1.25 V peak to peak, biased to a common mode voltage of 2.0 V. In addition the input circuit must provide proper transmission line termination (or proper load resistors in an amplifier-based solution) so the input of the impedance of the ADC analog inputs should be considered as well.

The clocking solution will have a direct impact on performance in terms of SNR, as shown in 图 103. The ADS54J54 is capable of a typical SNR of 66 dBFS for input frequencies of about 100 MHz (in 14-bit bypass digital mode), so we will want to have a clocking solution that can preserve this level of performance.

8.4 Detailed Design Procedure

The ADS54J54 has an input bandwidth of approximately 900 MHz, but we will consider an application involving the first or second Nyquist zones, so we will limit the frequency bandwidth here to be under 250 MHz. We will also consider a 50-ohm signal source, so the proper termination would be 50-Ω differential. As seen in 图 104 and 图 105, the input impedance of the analog input at 250 MHz is large compared to 50 Ω, so the proper termination can be 50-Ω differential as shown in 图 101. Splitting the termination into two 25-Ω resistors with an AC capacitor to ground provides a path to filter out any ripple on the common mode that may result from any amplitude or phase imbalance of the differential input, improving SFDR performance. The ADS54J54 provides a VCM output that may be used to bias the input to the desired level, but as seen in 图 67 the signal is internally biased inside the ADC so an external biasing to VCM is not required. If an external biasing to VCM were to be employed, the VCM voltage may be applied to the mid-point of the two 25-Ω termination resistors in 图 101.

For the clock input, 图 103 shows the SNR of the device above 100 MHz begins to degrade with external clock jitter of greater than 100 fs rms, so we will recommend the clock source be limited to approximately 100 fS of rms jitter. For the ADS54J54 EVM, the LMK04828 clock device is capable of providing a low-jitter sample clock as well as providing the SYSREF signal required as shown in 图 62 and 图 63, so that clocking device is one good choice for the clocking solution for the ADS54J54.

8.4.1 SNR and Clock Jitter

The signal-to-noise ratio of the channel is limited by three different factors: the quantization noise is typically not noticeable in pipeline converters and is 84 dB for a 14-bit channel. The thermal noise limits the SNR at low input frequencies while the clock jitter sets the SNR for higher input frequencies.

$$SNR_{ADC}[dBc] = -20 \cdot \log \sqrt{\left(10^{-\frac{SNR_{Quantizatoin\ Noise}}{20}}\right)^2 + \left(10^{-\frac{SNR_{Thermal\ Noise}}{20}}\right)^2 + \left(10^{-\frac{SNR_{Jitter}}{20}}\right)^2} \quad (1)$$

Calculate the SNR limitation due to sample clock jitter using the following:

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Detailed Design Procedure (接下页)

$$SNR_{Jitter}[dBc] = -20 \cdot \log(2\pi \cdot f_{in} \cdot T_{Jitter}) \quad (2)$$

The total clock jitter (t_{Jitter}) has two components – the internal aperture jitter (98 fs for ADS54J54), which is set by the noise of the clock input buffer, the external clock jitter, and the jitter from the analog input signal. Calculate total clock jitter using the following:

$$T_{Jitter} = \sqrt{(T_{Jitter,Ext.Clock_Input})^2 + (T_{Aperture_ADC})^2} \quad (3)$$

External clock jitter can be minimized by using high quality clock sources and jitter cleaners, as well as bandpass filters at the clock input while a faster clock slew rate improves the channel aperture jitter.

The ADS54J54 has a thermal noise of 66 dBFS and internal aperture jitter of 98 fs. The SNR depending on amount of external jitter for different input frequencies is shown in 图 103.

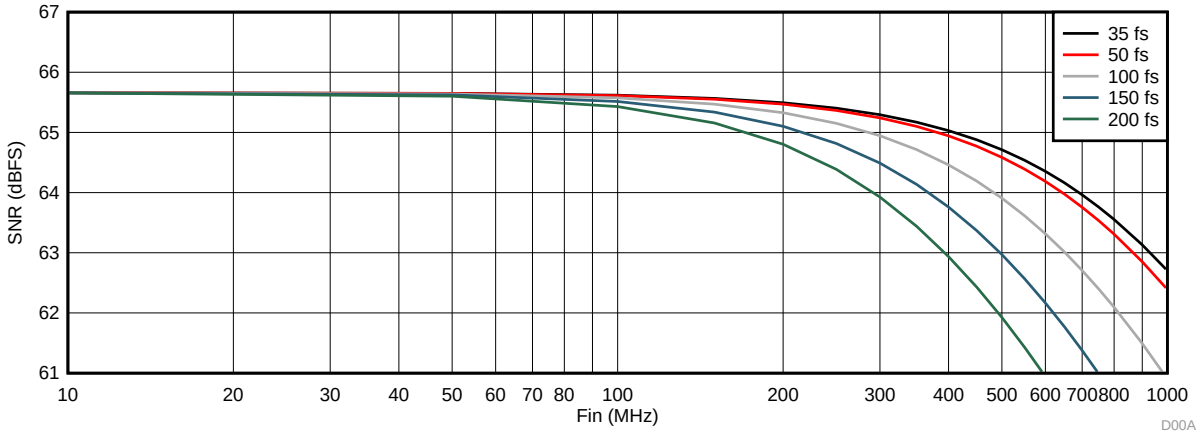

图 103. SNR vs Input Frequency and External Clock Jitter

8.5 Application Curves

图 104 and 图 105 show the differential impedance between the channel INP and INM pins. The impedance is modeled as a parallel combination of RIN and CIN (RIN || 1 / jwCIN).

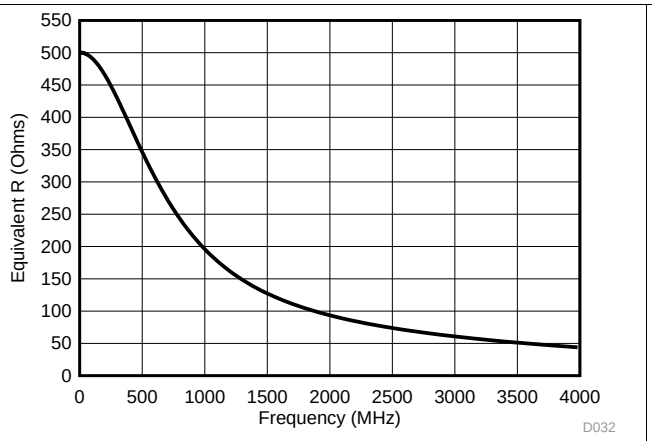

图 104. Equivalent R

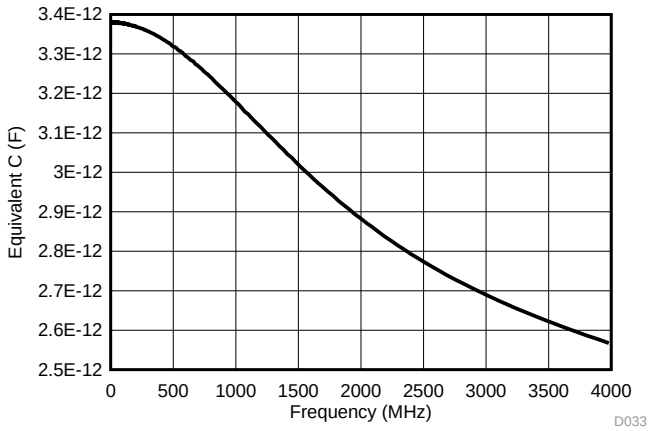

图 105. Equivalent C

9 Power Supply Recommendations

The device requires a 1.8-V nominal supply for AVDDC, IOVDD, PLLVDD, and DVDD. The device also requires a 1.9-V supply for AVDD18 and a 3.3-V supply for AVDD33. There are no specific sequence power-supply requirements during device power-up. AVDD, DVDD, IOVDD, PLLVDD, and AVDD33 can power up in any order.

10 Layout

10.1 Layout Guidelines

The Device EVM layout can be used as a reference layout to obtain the best performance. A layout diagram of the EVM top layer is provided in 图 107. Some important points to remember during laying out the board are:

- Analog inputs are located on opposite sides of the device pinout to ensure minimum crosstalk on the package level. To minimize crosstalk on-board, the analog inputs should exit the pinout in opposite directions, as shown in the reference layout of 图 107 as much as possible.
- In the device pinout, the sampling clock is located on a side perpendicular to the analog inputs in order to minimize coupling between them. This configuration is also maintained on the reference layout of 图 107 as much as possible.
- Digital outputs should be kept away from the analog inputs. When these digital outputs exit the pinout, the digital output traces should not be kept parallel to the analog input traces because this configuration may result in coupling from digital outputs to analog inputs and degrade performance. The digital sample data rate can be as high as 5.0 Gsps, so care must be taken to maintain the signal integrity of these signals. A low-loss dielectric circuit board is recommended or else these traces should be kept as short as possible. These traces should be kept away from the analog inputs ad n clock input to the device as well.
- At each power-supply pin, a 0.1-μF decoupling capacitor should be kept close to the device. A separate decoupling capacitor group consisting of a parallel combination of 10-μF, 1-μF, and 0.1-μF capacitors can be kept close to the supply source.

10.1.1 CML SerDes Transmitter Interface

Each of the 5 Gbps SerDes CML transmitter outputs requires AC coupling between transmitter and receiver. The differential pair should be terminated with a 100-Ω resistor as close to the receiving device as possible to avoid unwanted reflections and signal degradation.

10.2 Layout Example

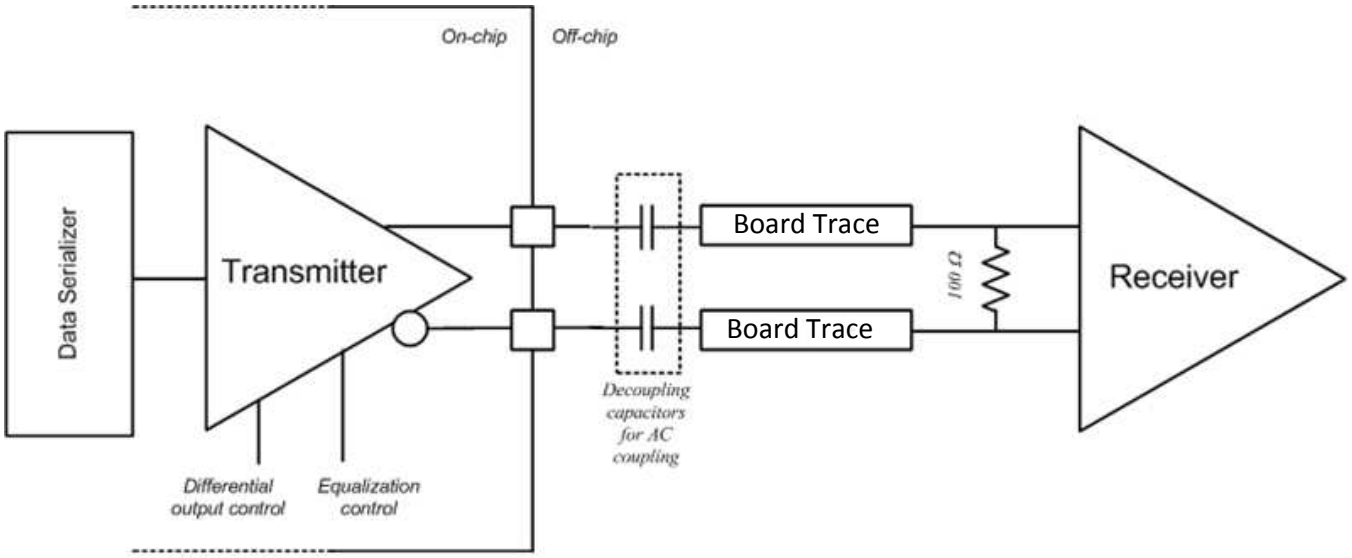

图 106. Layout Example Schematic

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Layout Example (接下页)

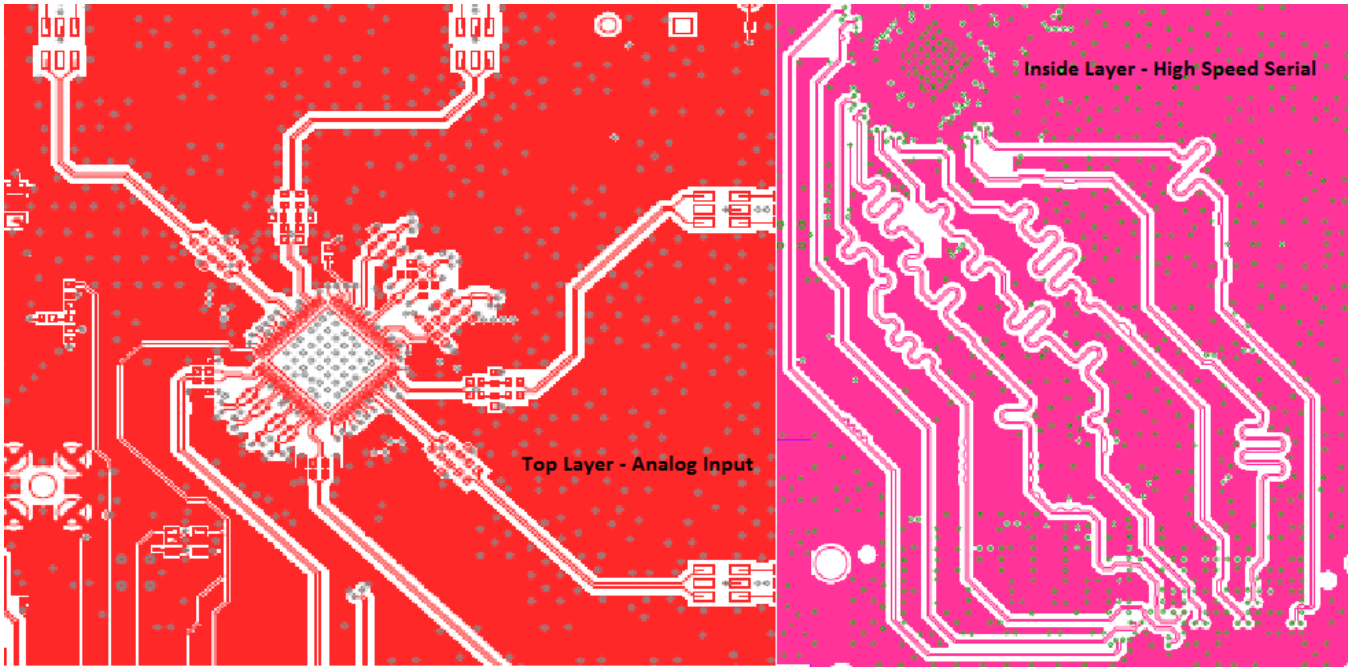

图 107. Top and Bottom Layers

11 器件和文档支持

11.1 商标

PowerPAD is a trademark of Texas Instruments.

11.2 静电放电警告

这些装置包含有限的内置 ESD 保护。 存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.3 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
ADS54J54IRGCR	Active	Production	VQFN (RGC) | 64	2000 | LARGE T&R	Yes	NIPDAUAG	Level-3-260C-168 HR	-40 to 85	AZ54J54
ADS54J54IRGCT	Active	Production	VQFN (RGC) | 64	250 | SMALL T&R	Yes	NIPDAUAG	Level-3-260C-168 HR	-40 to 85	AZ54J54

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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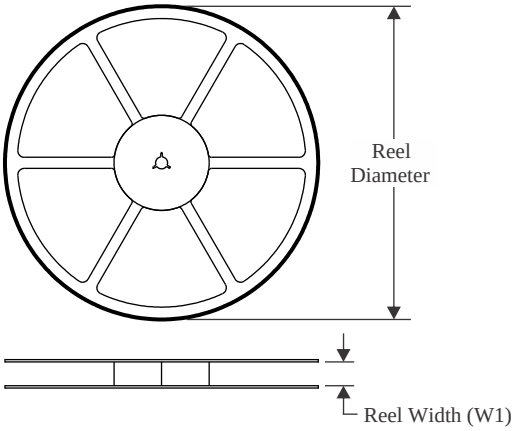
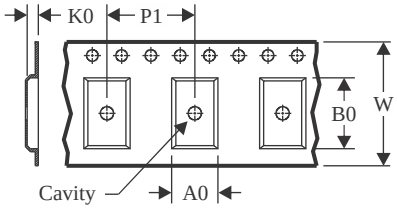
TAPE AND REEL INFORMATION

REEL DIMENSIONS

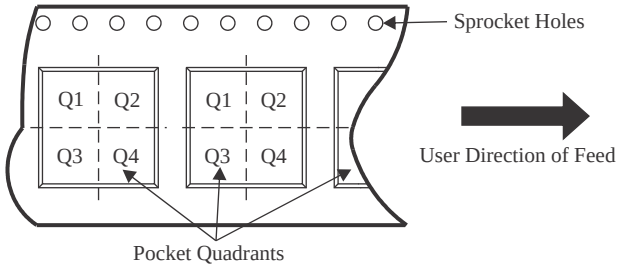


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

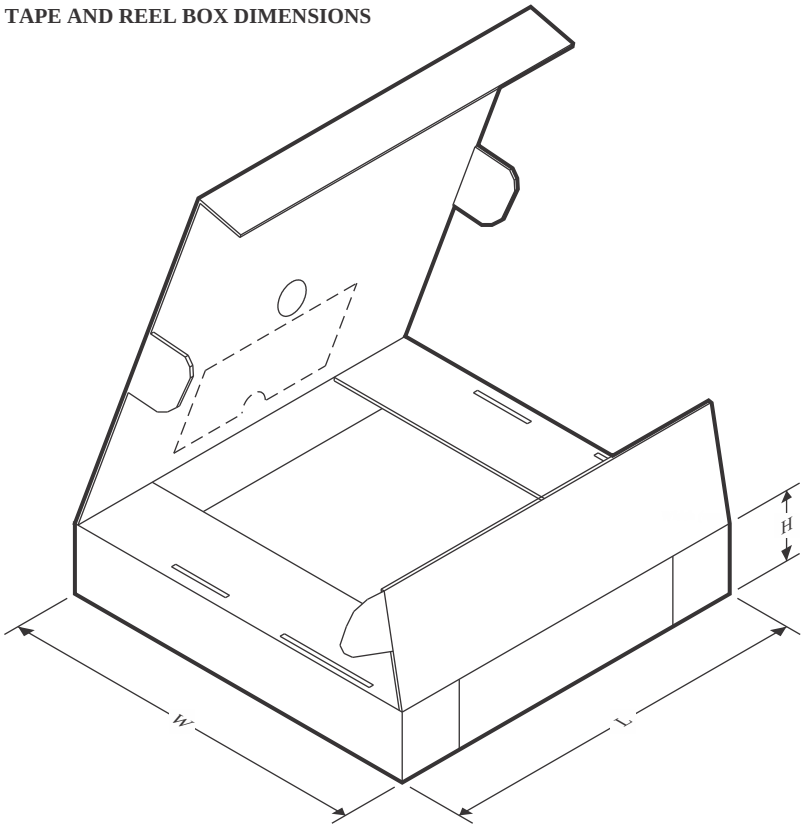
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS54J54IRGCR	VQFN	RGC	64	2000	330.0	16.4	9.3	9.3	1.5	12.0	16.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADS54J54IRGCR	VQFN	RGC	64	2000	350.0	350.0	43.0

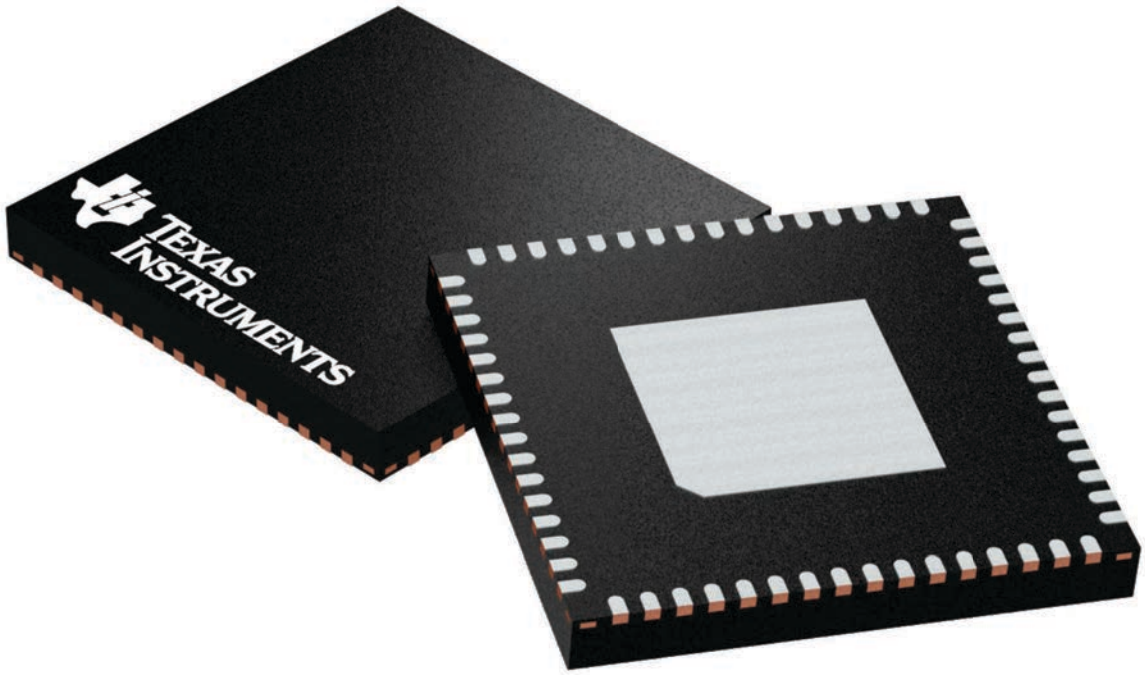
GENERIC PACKAGE VIEW

RGC 64

VQFN - 1 mm max height

9 x 9, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

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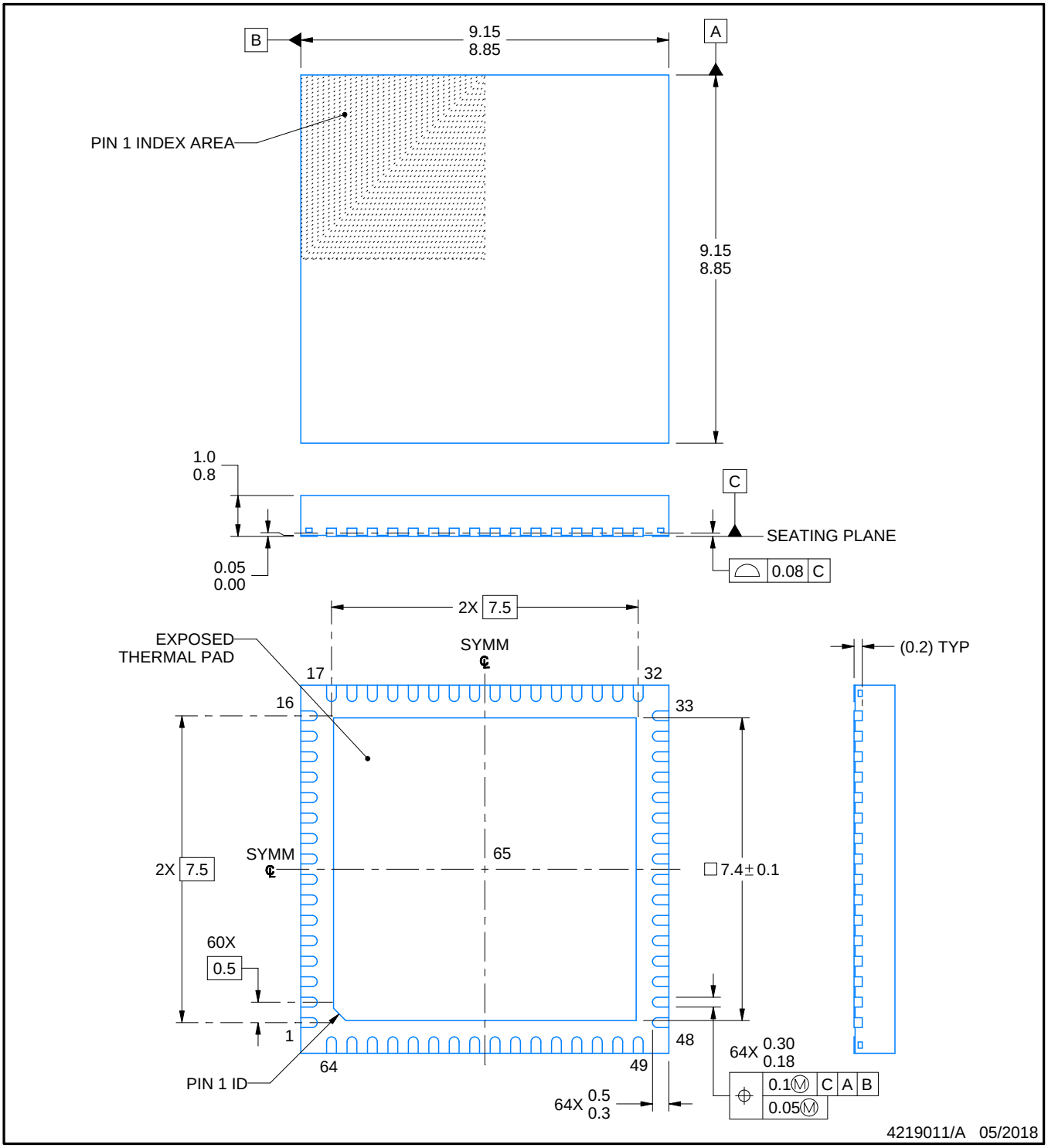
RGC0064H

PACKAGE OUTLINE

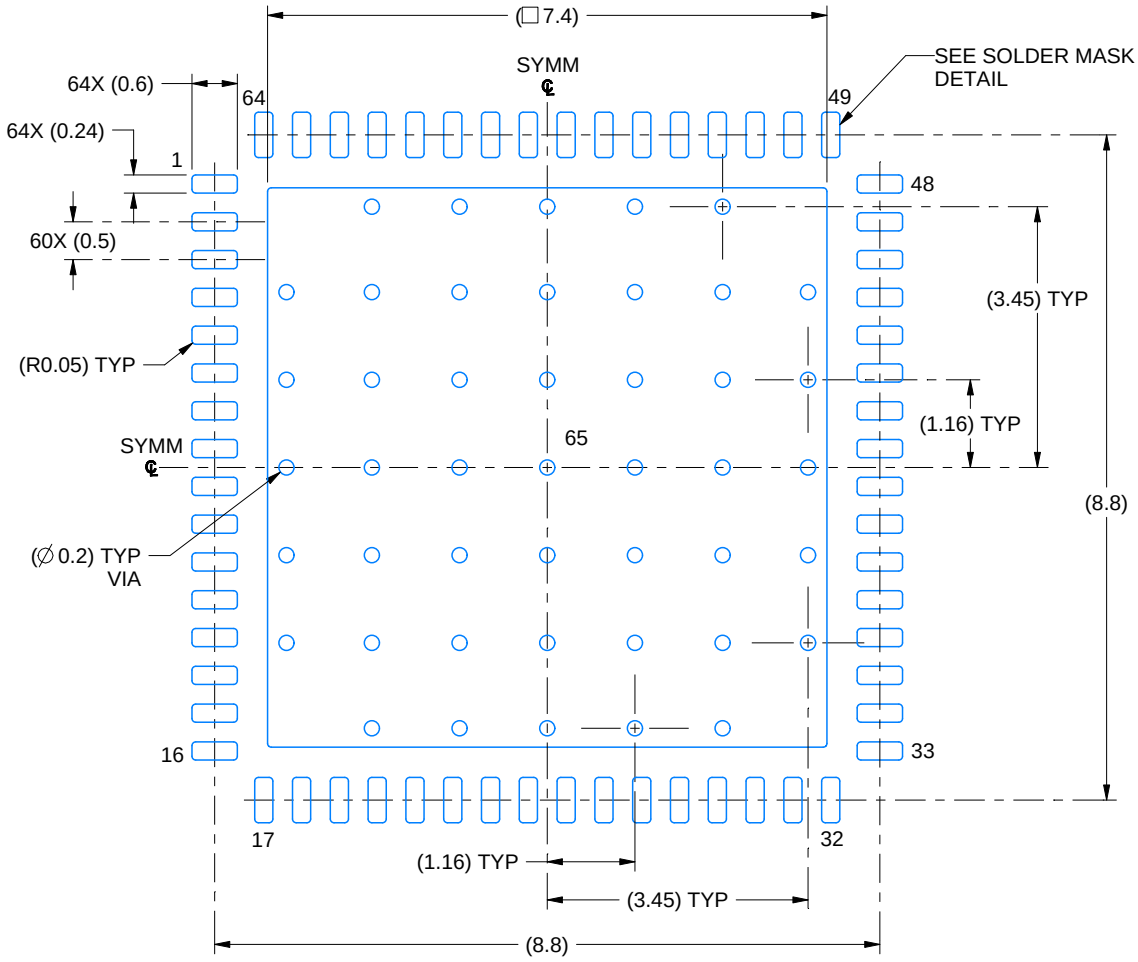
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

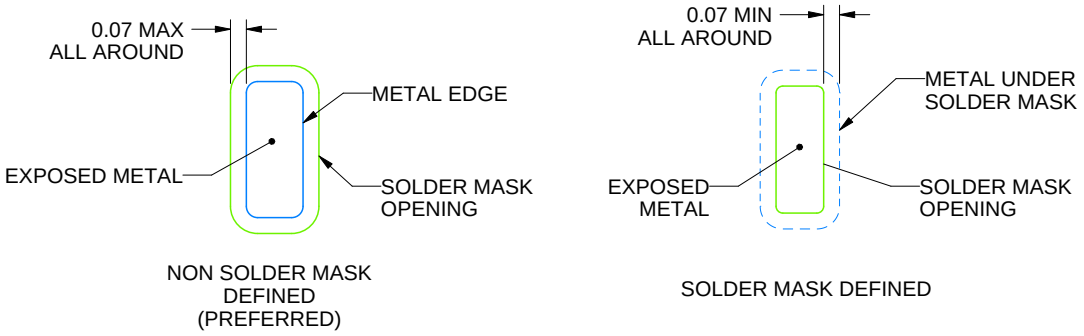


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

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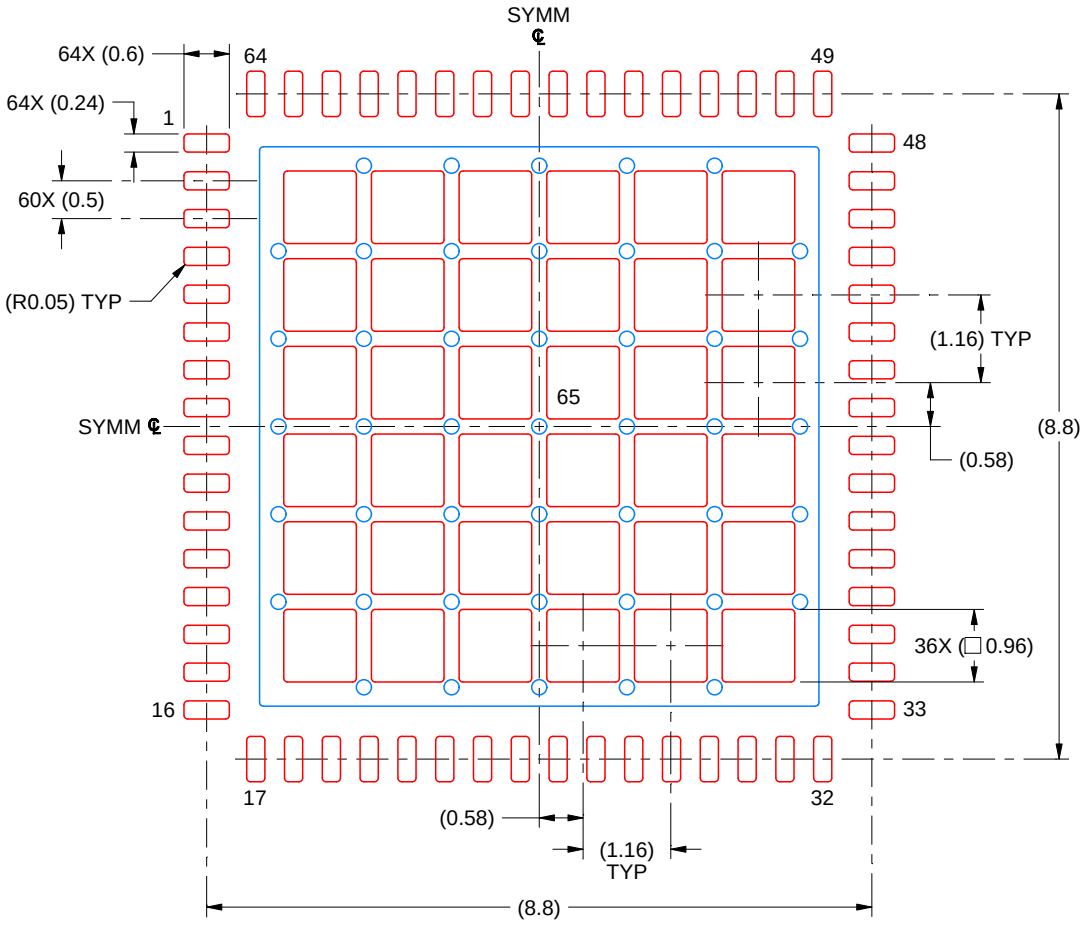
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 MM THICK STENCIL
SCALE: 10X

EXPOSED PAD 65
61% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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